

# Scanning Electron Microscopy Techniques

2019-2020

- **Introduction to electron microscopy** (by E. Oveisi)  
**Electron matter interaction**
- **SEM setup**
  - Electron sources**
  - Lenses**
  - Vacuum system**
  - Detection system**
- **Imagining with SEM**
  - Operation, Signals**
  - Contrast mechanism**
  - Interpretation of images, Challenges**
  - Related techniques** (By M. Cantoni)
  - Advanced and high-resolution SEM**
- **Chemical analysis and Monte Carlo simulations**
- **Focused ion beam**

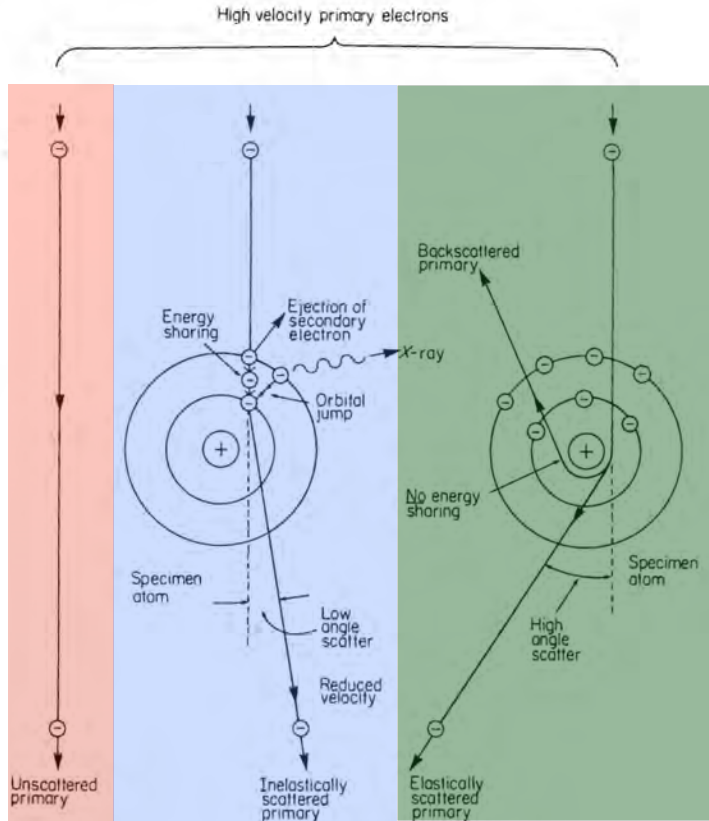
# Why use electrons?

	Advantageous	Disadvantageous
Visible light	Not very damaging Easily focused Eye detector	Long wavelengths (400 nm)
X-rays	Small wavelength (Angstrom) Good penetration	Hard to focus Damage sample
Neutrons	Low sample damage Small wavelength (pm)	How to produce? How to focus?
Electrons	Small wavelength (pm) Can be focused	Damage sample Poor penetration

High energy electrons have a short wavelength  
 Easy to produce high brightness electron beams  
 Easy to manipulate : focused  
**Interact strongly with matter**

Electron microscopes are used not only for obtaining good resolution images but also:

- **can be used as a diffractometer (TEM)**
- **for chemical analyses (SEM and TEM)**
- **for imaging/measuring strain field in the sample (SEM and TEM)**
- **etc.**



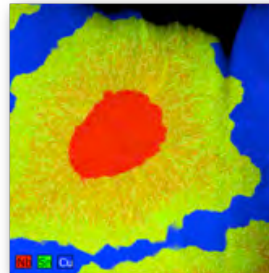
**Inelastic events:** The result is a **transfer of beam energy** to the specimen atom (**energy loss**) and a potential expulsion of an electron from that atom as a **secondary electron (SE)**.

If the vacancy due to the creation of a secondary electron is filled from a higher level orbital, an X-Ray characteristic of that energy transition is produced.



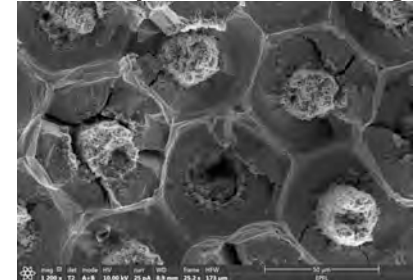
That's why TEMs are shielded!

Characteristic X-rays

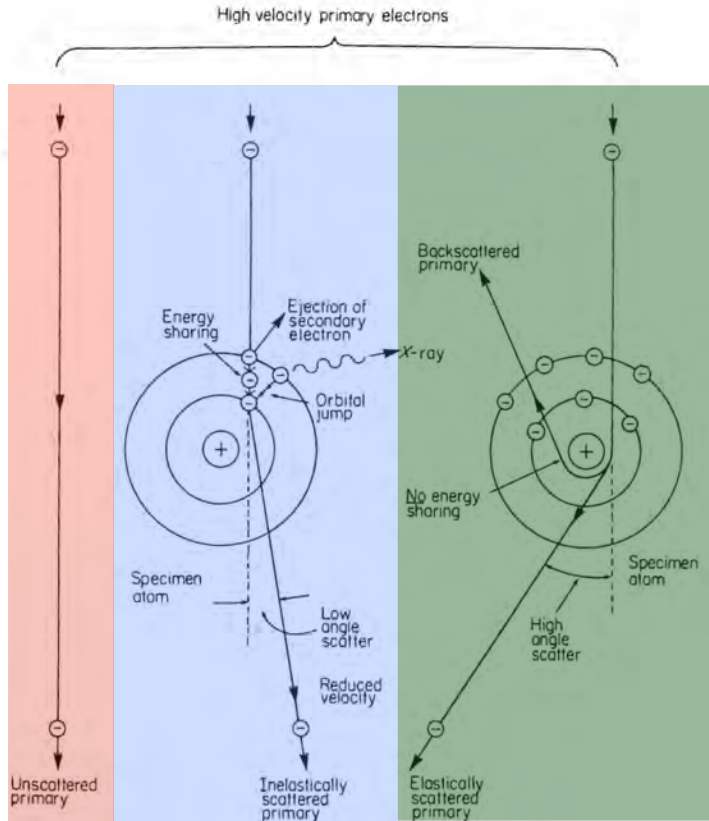


Chemical composition

Secondary electron SEM image

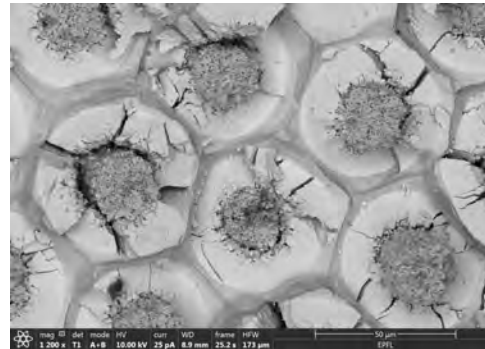


Topography

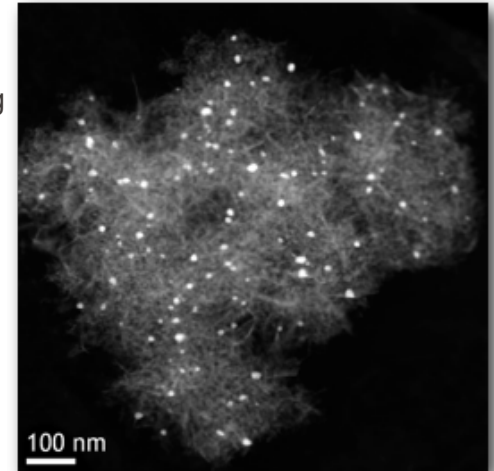


**Elastic events** occur when a beam electron interacts with the electric field of the nucleus of a specimen atom, resulting in a change in the direction of the beam electron **without a significant change in the energy** of the beam electron ( $< 1$  eV).

Heavier atom => More backscattering

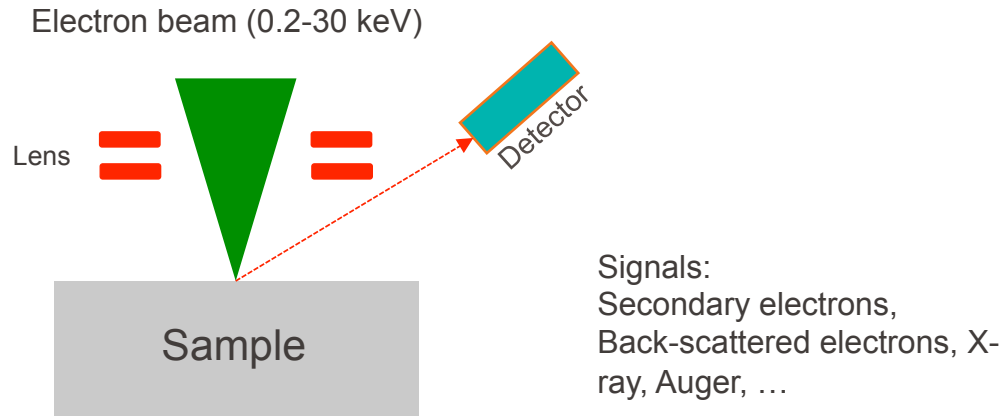


Larger nucleus => More scattering



# Types of electron microscopes

## Scanning Electron Microscope (SEM)

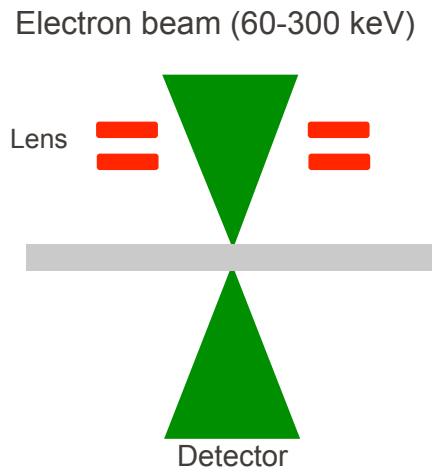


Salt grains

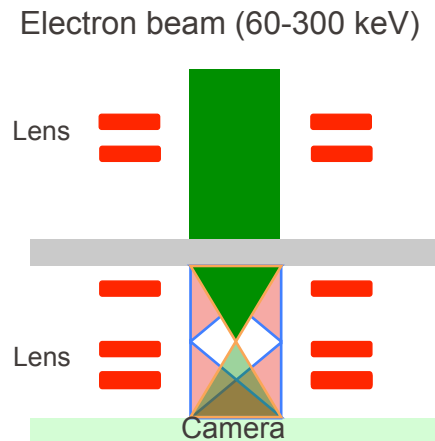
# Types of electron microscopes

## Transmission Electron Microscope (TEM)

- Scanning mode (STEM)



- Conventional mode (CTEM or TEM)



Sample



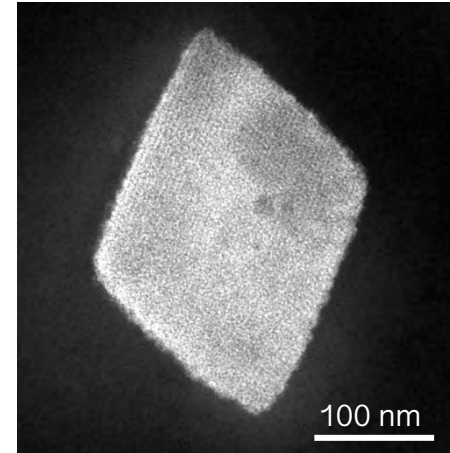
# Types of electron microscopes

## ■ SEM



Salt grains

## ■ TEM



Cu-based metal-organic framework



# Types of electron microscopes

- SEM

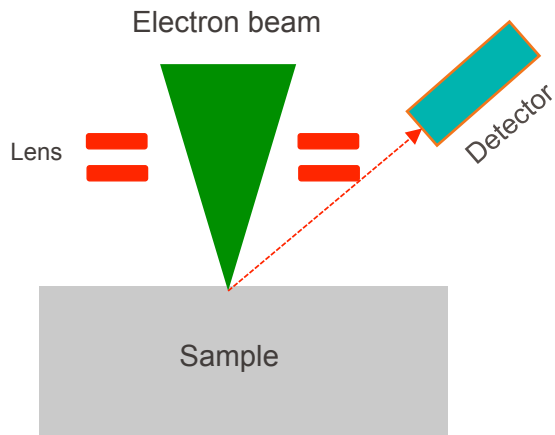


- TEM

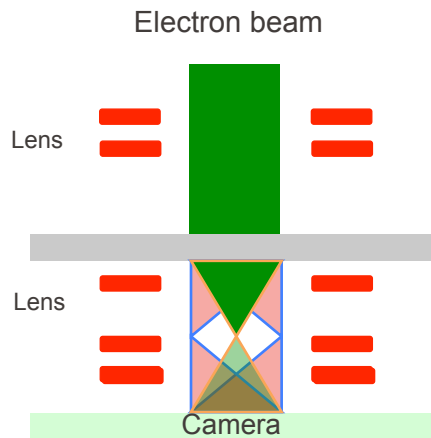


# Components of an EM

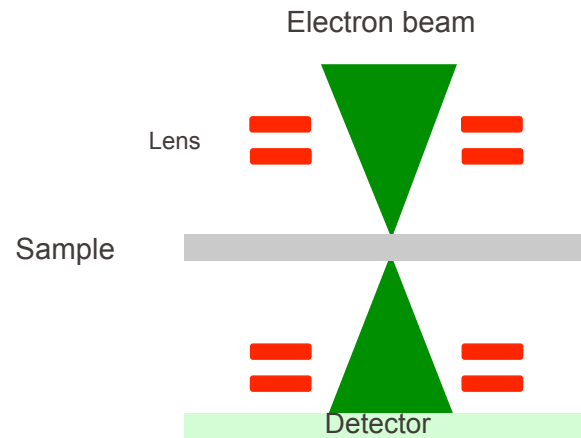
## SEM



## TEM

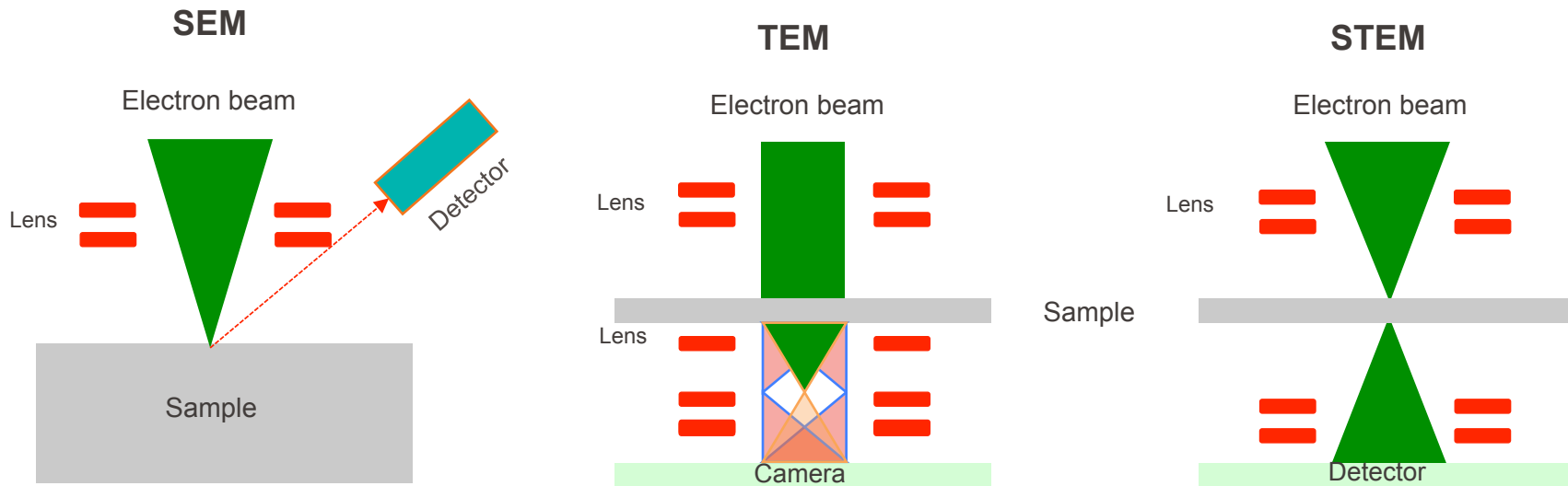


## STEM



Vacuum system  
Electron gun  
Lenses  
Detectors

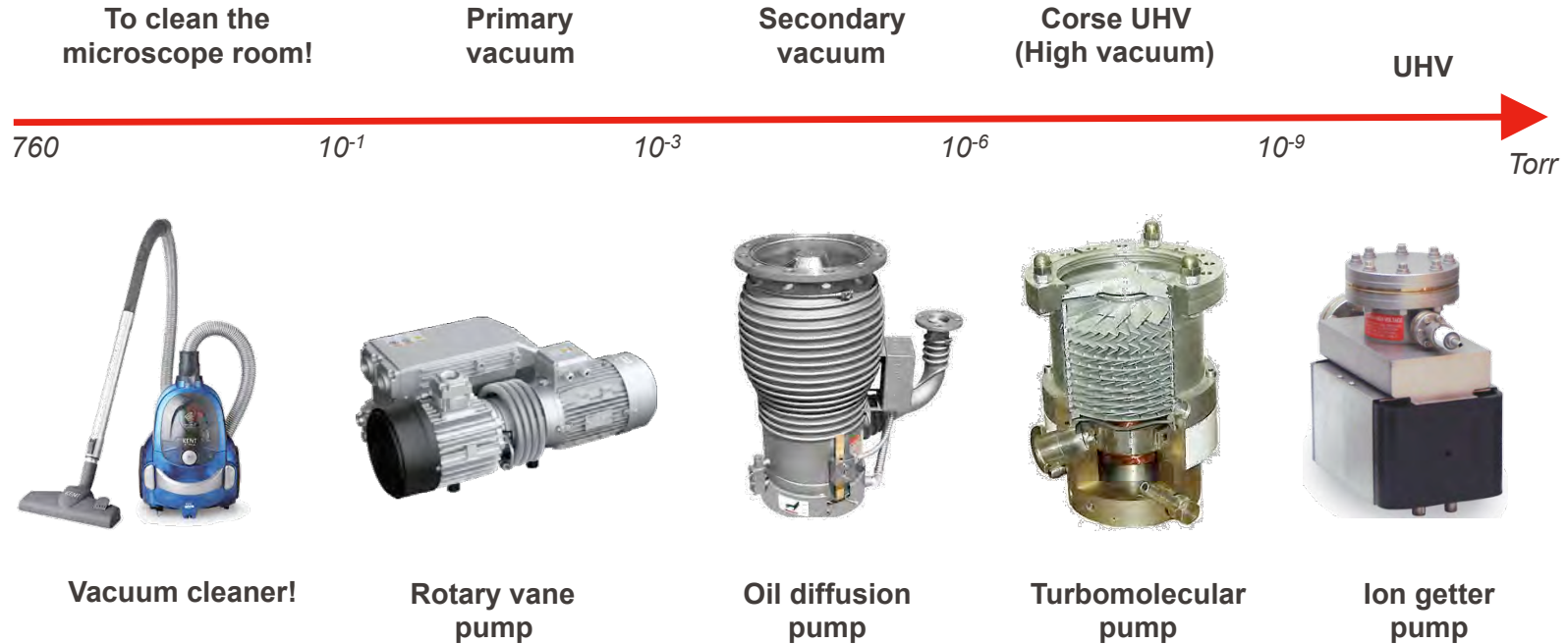
# Components of an EM – Vacuum system



## Why we need vacuum?

1. Electron propagation is only possible through vacuum ( $e^-$  interacts heavily with the matter)
2. Need a good vacuum system to reduce contamination and surface modification

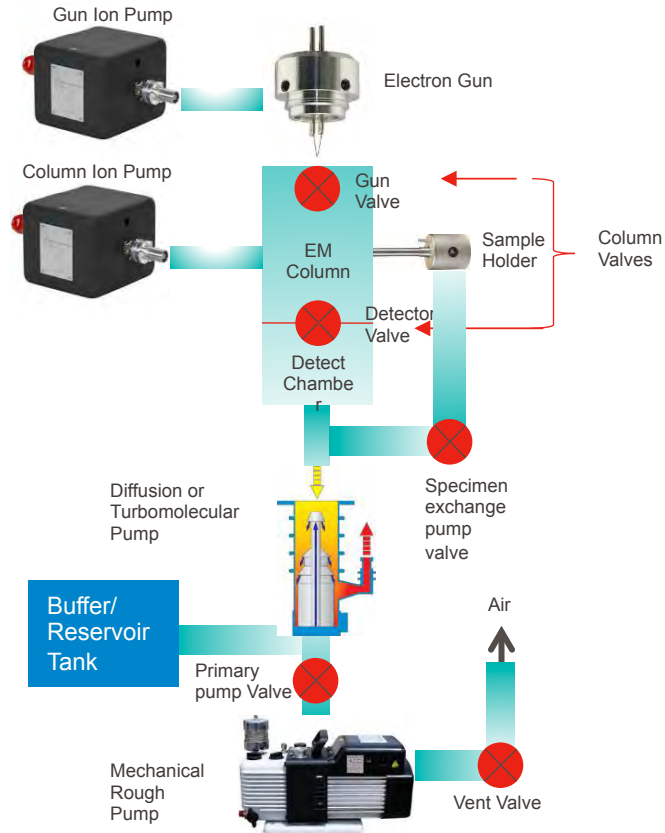
# Vacuum system



Different kinds of vacuum pumps have different range where they are effective

$$760 \text{ Torr} = 1 \text{ Atmosphere} = 1.013 \text{ Bar} = 101.325 \text{ KPa}$$

# Vacuum system



**UHV is not needed in all parts of the microscope**

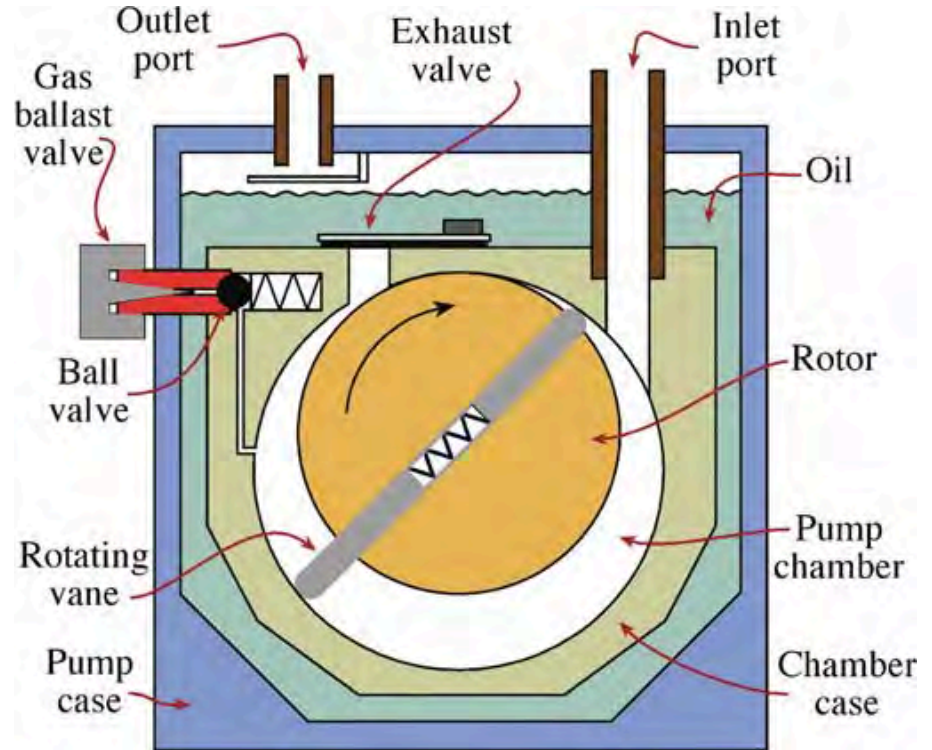
- **Primary vacuum ( $>0.1$  Pa)**
  - Mechanical pump
- **Secondary to high vacuum**  
**Detector or viewing chamber ( $<10^{-4}$  Pa)**
  - Oil diffusion pump
  - Turbomolecular pump
- **High and ultra-high vacuum**  
**Gun & specimen area ( $<10^{-6}$  Pa)**
  - Ion getter pump
  - Cold trap

Vacuum level in space: 1 Pa at 100km above earth  
 760 Torr = 1 Atmosphere = 1.013 Bar = 101.325 KPa

# Vacuum system

## Rotary (mechanical) vane pump

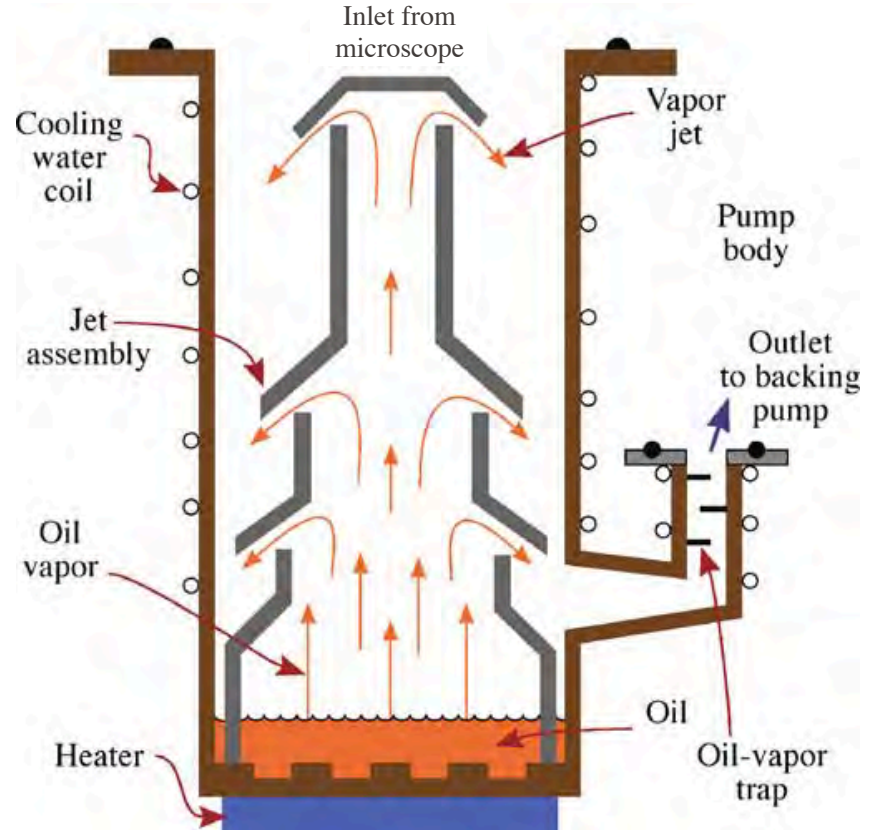
- Uses oil
- Noisy



# Vacuum system

## Oil diffusion pump

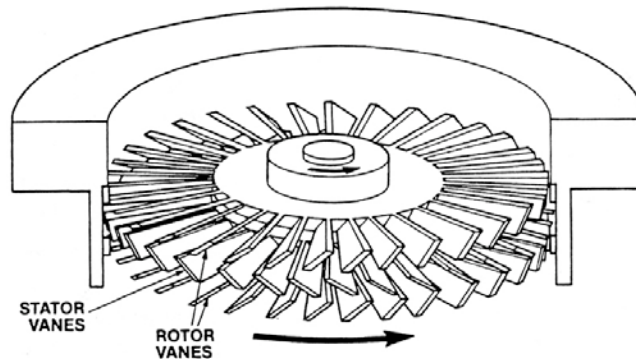
- Vibration free
- Contamination possible oil vapor
- High pumping capacity





## Turbomolecular pump

- Uses a turbine to force gases from the microscope
- Rotation speed 20'000-50'000 rpm
- Magnetic bearings
- Pumping volumes 50-500 l/s
- Can start (slowly) at ambient pressures, increasing speed as the pressure is lowered
- Ultimately providing UHV conditions at high enough speeds



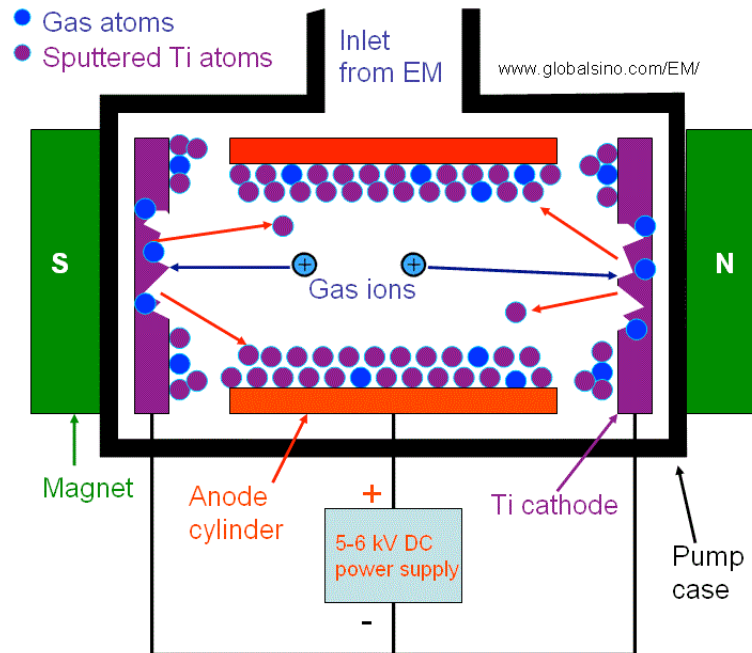
## Ion getter pump

- No vibrations
- No exit = trapping: improves vacuum !

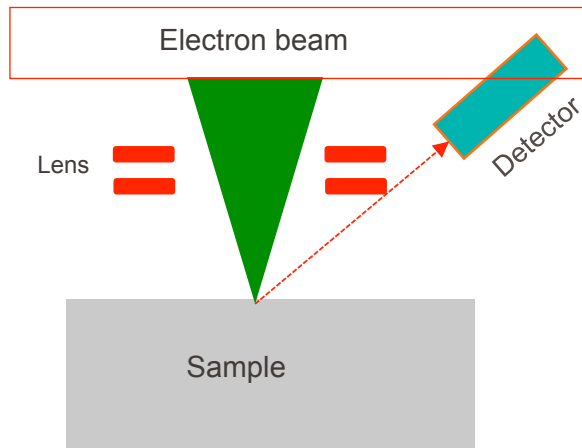
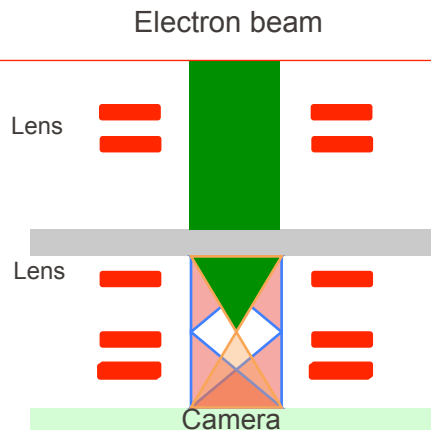
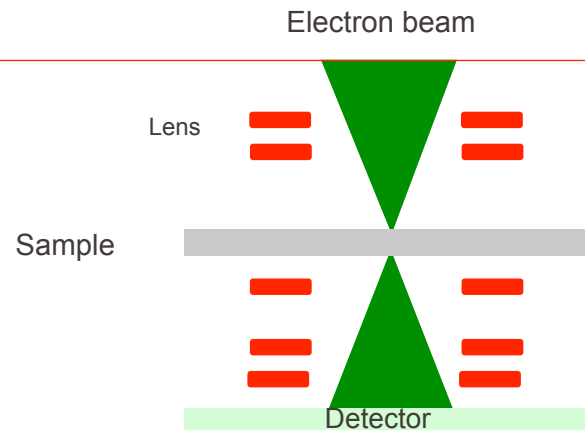
The ion pump emits electrons from a cathode. These ions spiral in a magnetic field and ionize air molecules, which are then attracted to the cathode. The energetic gas ions sputter Ti atoms from the cathode and they condense throughout the pump chamber, mainly on the cylindrical anode, trapping gas atoms.

Thus ion pumps remove gas atoms in two ways;

- by chemisorption on the anode surfaces
- by electrical attraction to the cathodes.



# Components of an EM

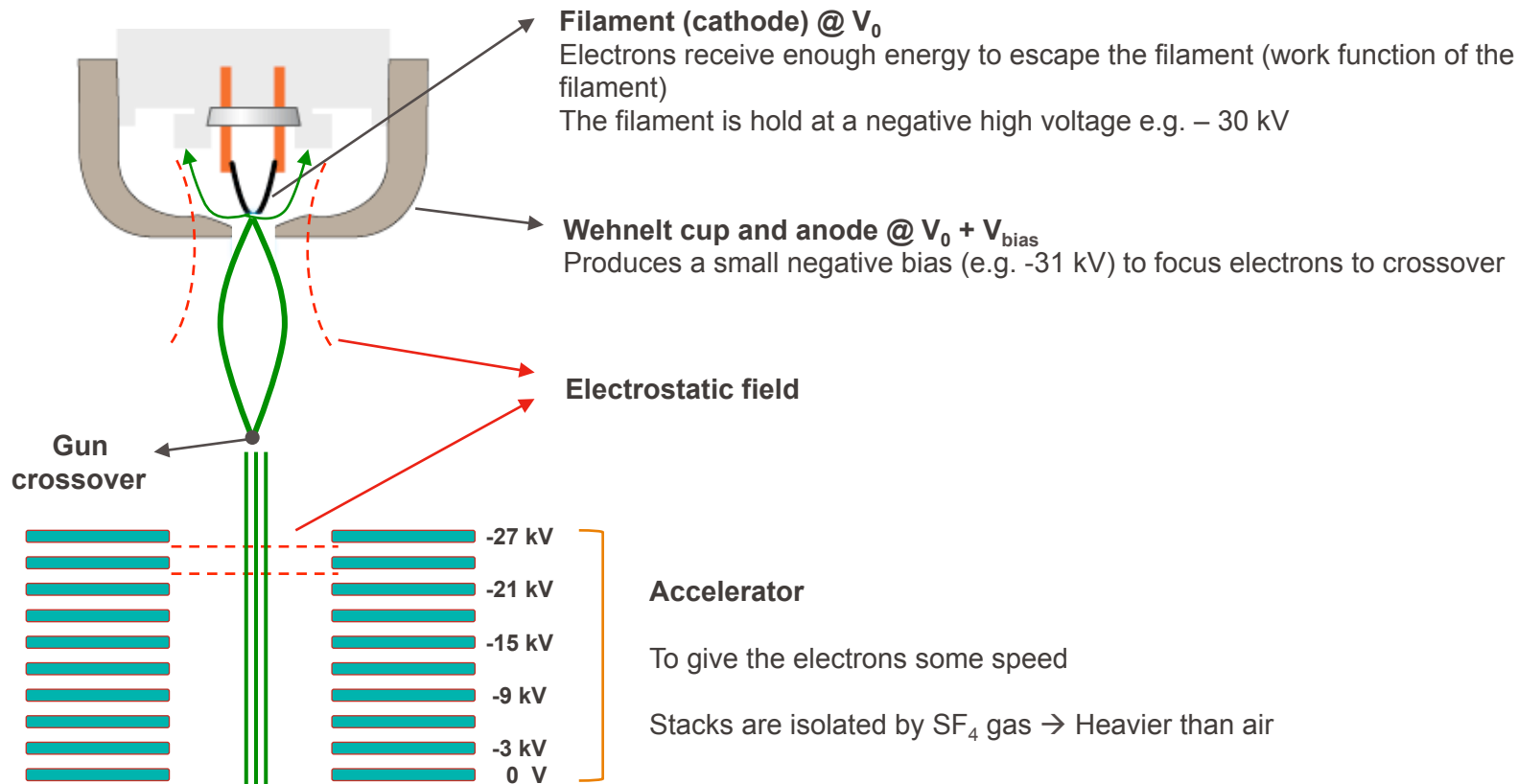
**SEM****TEM****STEM**

Vacuum system  
**Electron gun**  
Lenses  
Detectors

# Electron gun

- Purpose: To create a narrow intense beam of electrons
- 3 types of electron guns:
  - Thermionic (Thermal)  
Heat only
  - Cold field emission  
Electric field: Potential (voltage) difference
  - Heat assisted field emission: Schottky emitter  
Heat + Electric field

# Thermionic gun



# Thermionic gun



- Filament as a light bulb : W wire or  $\text{LaB}_6$  crystal
  - Filament is heated to overcome the work-function to release electrons to vacuum level
  - Tungsten wire heated to  $\sim 2800\text{K}$  |  $\text{LaB}_6$  crystal heated to  $1900\text{K}$
  - Must heat slowly otherwise burn out the filament or crystal damage
- Heating current (filament current) is NOT beam current!
- Saturation point of the filament
  - Optimized electron output | Filament life time

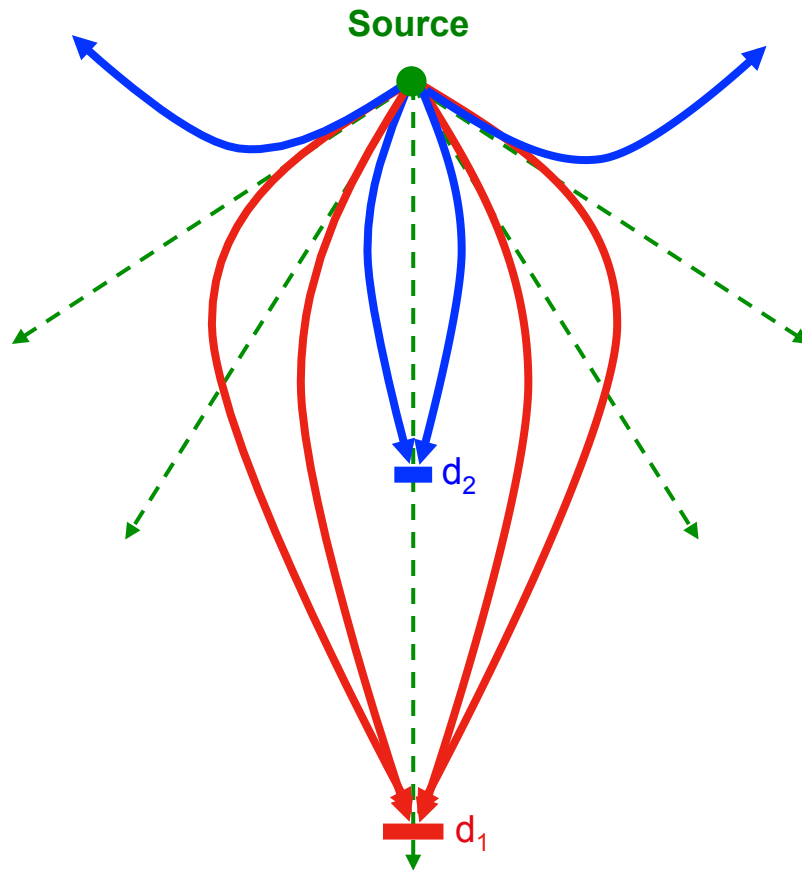
**Bias condition #1**

- Large collection angle
- Large cross over ( $d_1$ )
- Large probe

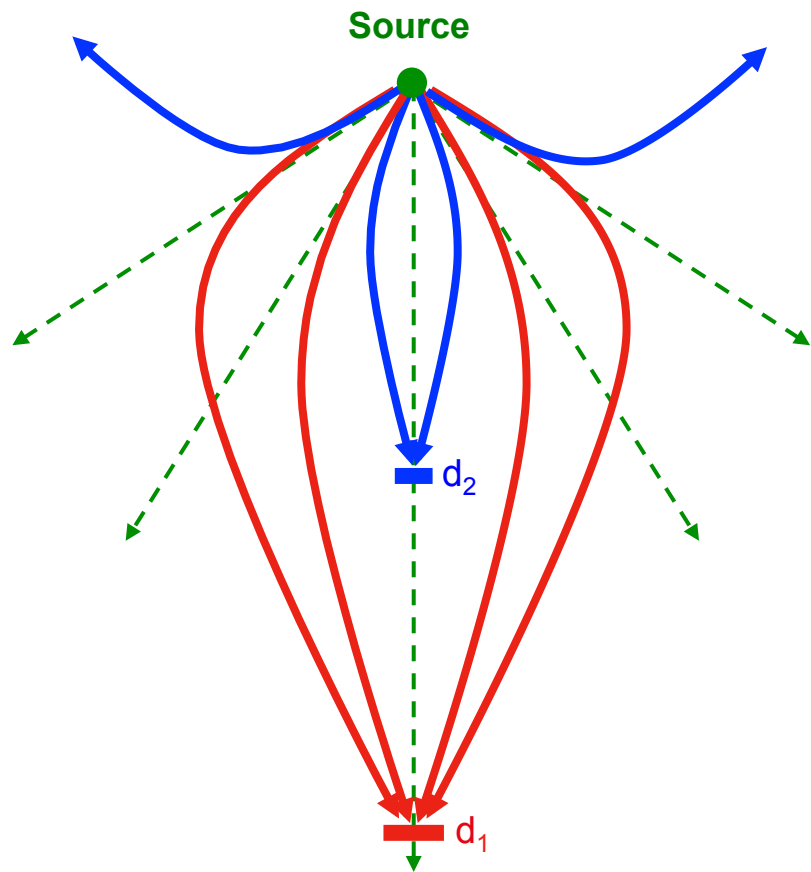
**Bias condition #2**

Stronger = more negative

- Narrower collection angle
- Smaller cross-over ( $d_2$ )
- Smaller probe
- Less total beam current





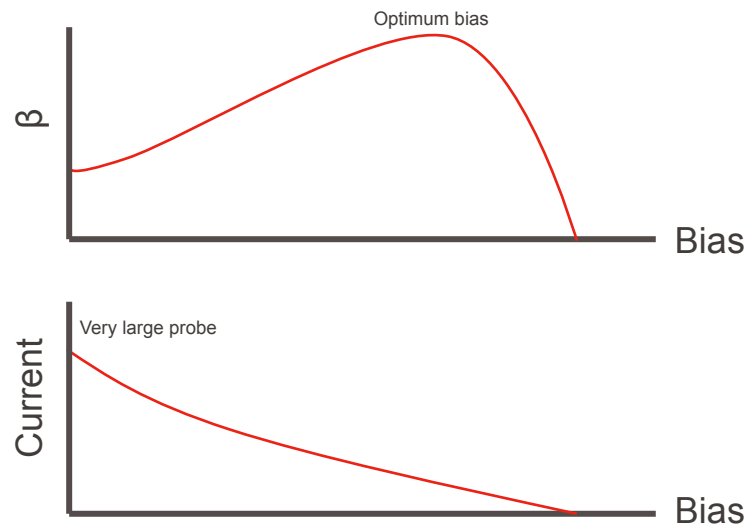


Current density

$$\beta \mid \text{brightness} = \frac{\text{Beam current}}{(\text{Area}) (\text{Solid angle})}$$

Crossover size      Collection angle

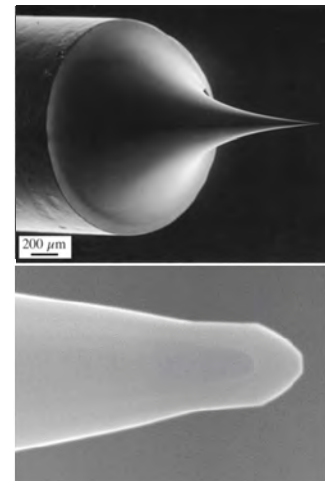
A diagram of a cone with a green circular base of area  $dS$  and height  $dl$ . The solid angle is labeled  $d\Omega$  and the half-angle is  $d\alpha$ .



# Field Emission Gun (FEG)

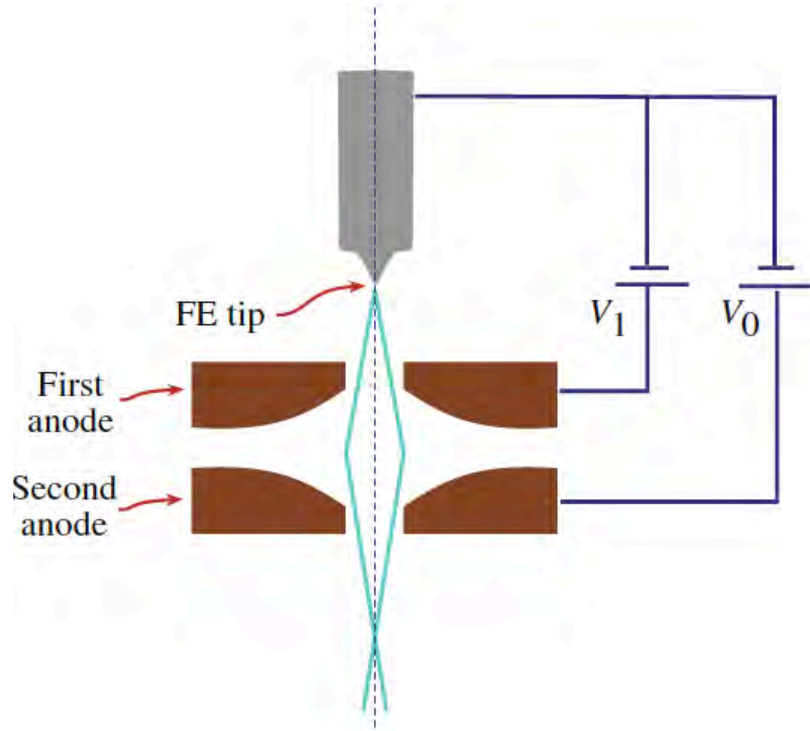
By applying an electric field of very high field strength at the surface of a metal, electrons are emitted even without heating the metal: *Cold field emission*

- Sharp tip is needed (less than 100 nm)
  - The strength of an electric field  $E$  is considerably increased at sharp points.
- Electrons can tunnel straight from the Fermi level out of the filament (usually tungsten).
- Surface has to be pristine (no contamination or oxide)
- 2 types of FEGs:
  - Cold FEG (Ultra-high vacuum condition needed)
    - $E \approx 10^9$  V/m
    - W mono-crystal with sharp tip (radius  $\sim 100$  nm)
  - Heat assisted FEG: Schottky effect\* (high vacuum is usually enough)
    - W crystal with ZrO surface treatments to lower the work-function
    - Can work with slightly poorer vacuum



\*Schottky effect is the effective decrease of the work function when an external field is applied at the metal surface.

# Field Emission Gun (FEG)



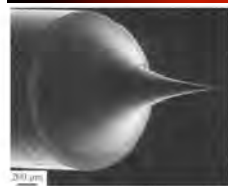
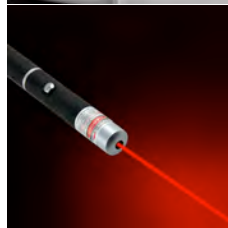
- Anode 1 provides the extraction voltage to pull electrons out of the tip.
- Anode 2 accelerates the electrons to the desired voltage.

The electrons are accelerated through the appropriate voltage by the second anode.

Intensity



Brightness



## Spatial coherency:

Do all the electrons come from the same direction?

An electron beam emanating from a small source size is said to have high **spatial coherency**.

## Temporal coherency:

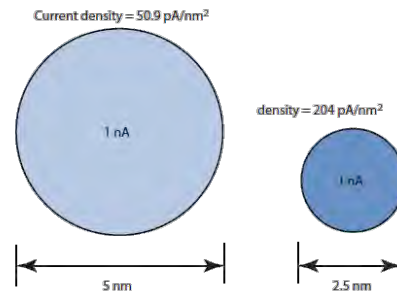
Do all the electrons have exactly the same speed/energy?

A beam with high **temporal coherency** will have electrons of the same wavelength.

## Important parameters

- Source and crossover size: determines the probe size ( $\rightarrow$  resolution)
- Energy spread: temporal coherency
- Emitted current and current density
- Brightness: current per surface unit and per solid angle
- Current stability
- Vacuum needed

$$\beta \mid \text{brightness} = \frac{\text{Beam current}}{(\text{Area}) (\text{Solid angle})}$$



## ■ Thermionic gun

- Analogous to volcano
- More electrons form a large tip (10-100  $\mu\text{m}$ )
- Different energies
- Different directions
- Simple to use & maintenance friendly
- Cheap
- Requires only moderate vacuum
- High total beam current
- Low brightness
- High energy spread
- Large source size (10-100  $\mu\text{m}$ )
- Limited lifetime ( $\sim 1000\text{h}$  for  $\text{LaB}_6$ )

## ■ FEG

- Analogous to child's slide (toboggan)
- Electrons from a very sharp tip radius  $\sim 100\text{nm}$
- Same energy
- Same direction
- High coherence (both spatial and temporal)
- Small energy dispersion ( $< 0.4\text{ eV}$ )  
→ higher resolution at lower energies
- High brightness
- Long lifetime  $> 1000\text{h}$
- Expensive
- Ultra-high vacuum necessary
- Cold FEG needs flushing after  $\sim 8\text{ hrs}$

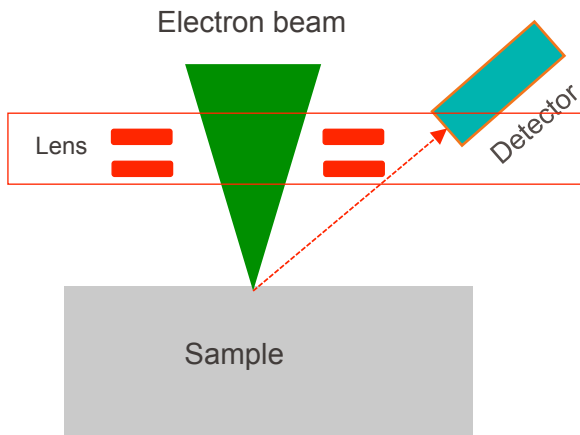
# Electron gun

	W	LaB6	FEG Schottky (ZrO/W)	FEG cold (W)
Crossover size (nm)	<b>&gt;10<sup>5</sup></b>	10 <sup>4</sup>	<b>10-100</b>	3
Emission current (μA)	<b>100</b>	20	<b>100</b>	20~100
Current density (A/m <sup>2</sup> )	<b>5</b>	10 <sup>2</sup>	<b>10<sup>5</sup></b>	10 <sup>6</sup>
Brightness B (A/m <sup>2</sup> sr)	<b>5x10<sup>9</sup></b>	5x10 <sup>10</sup>	<b>5x10<sup>12</sup></b>	10 <sup>13</sup>
Energy spread ΔE (eV)	2.3	1.5	0.6~0.8	0.3~0.7
Current stability (%/hr)	<1	<1	<1	<b>5</b>
Vacuum pressure (Pa)*	10 <sup>-3</sup>	10 <sup>-5</sup>	10 <sup>-7</sup>	10 <sup>-8</sup>
Vacuum temperature (K)	2800	1800	1800	300

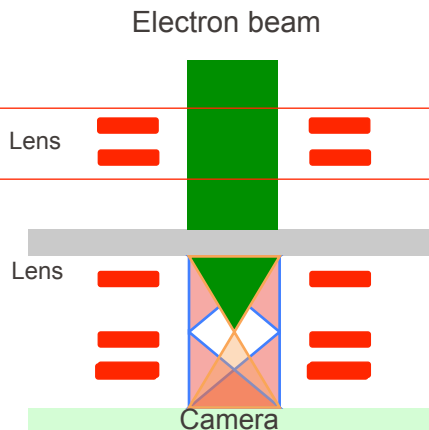
\* Might be one order lower

# Components of an EM

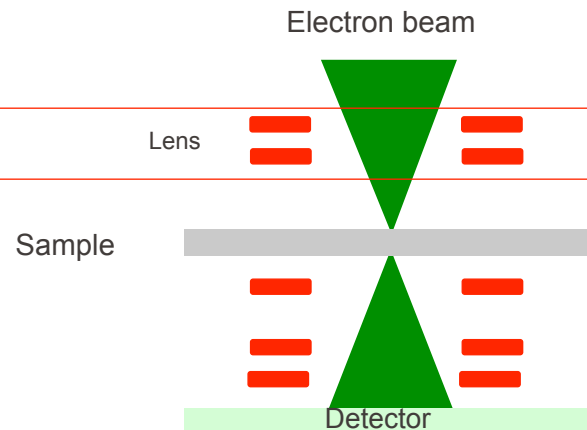
## SEM



## TEM



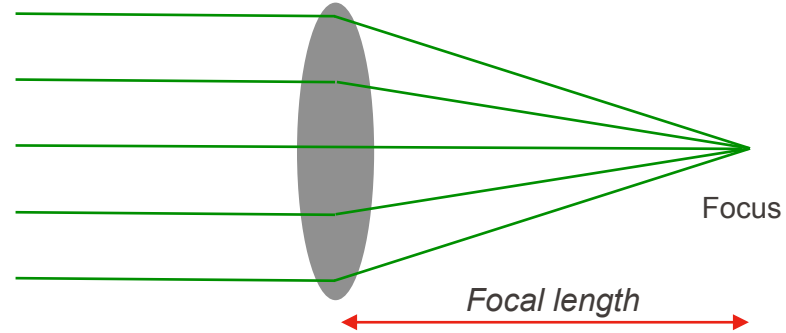
## STEM



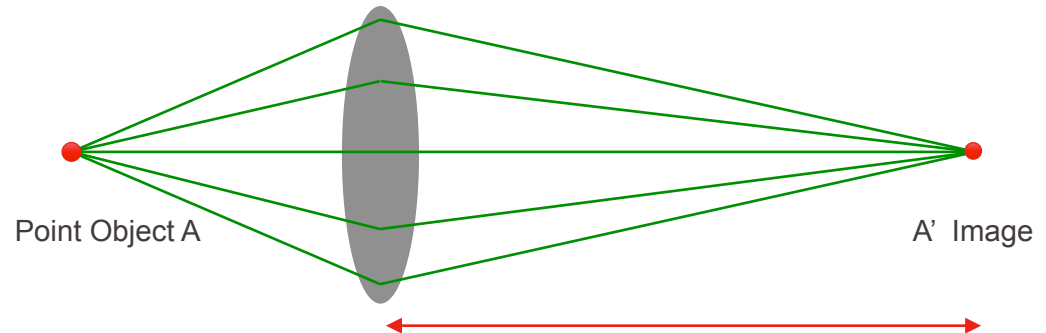
Vacuum system  
Electron gun  
**Lenses**  
Detectors



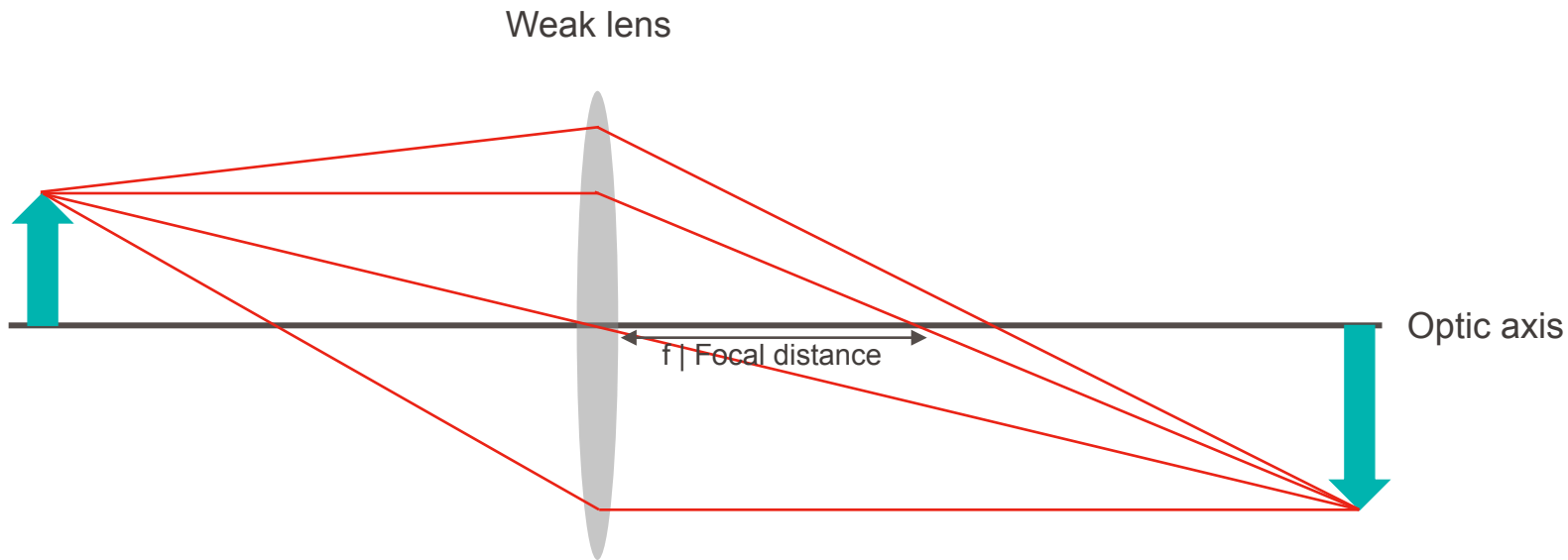
Lens bends beams to focus it to a point.



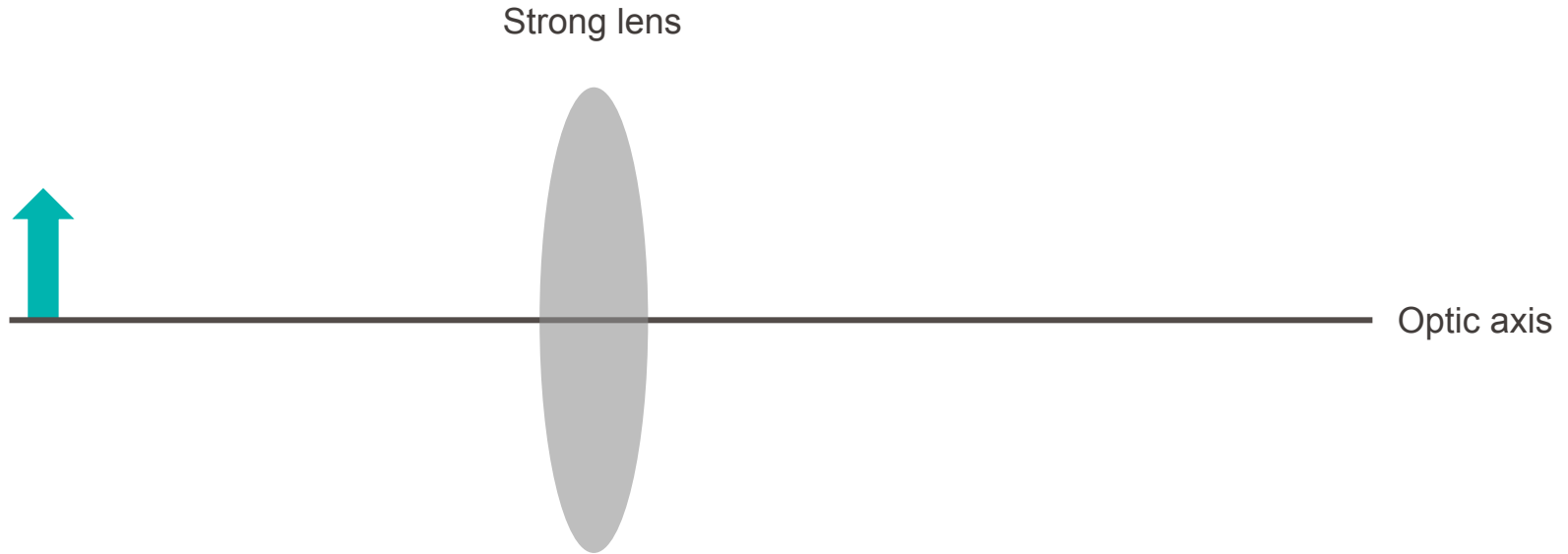
The rays emanating from a point in the object plane come to one common well defined point in image plane.



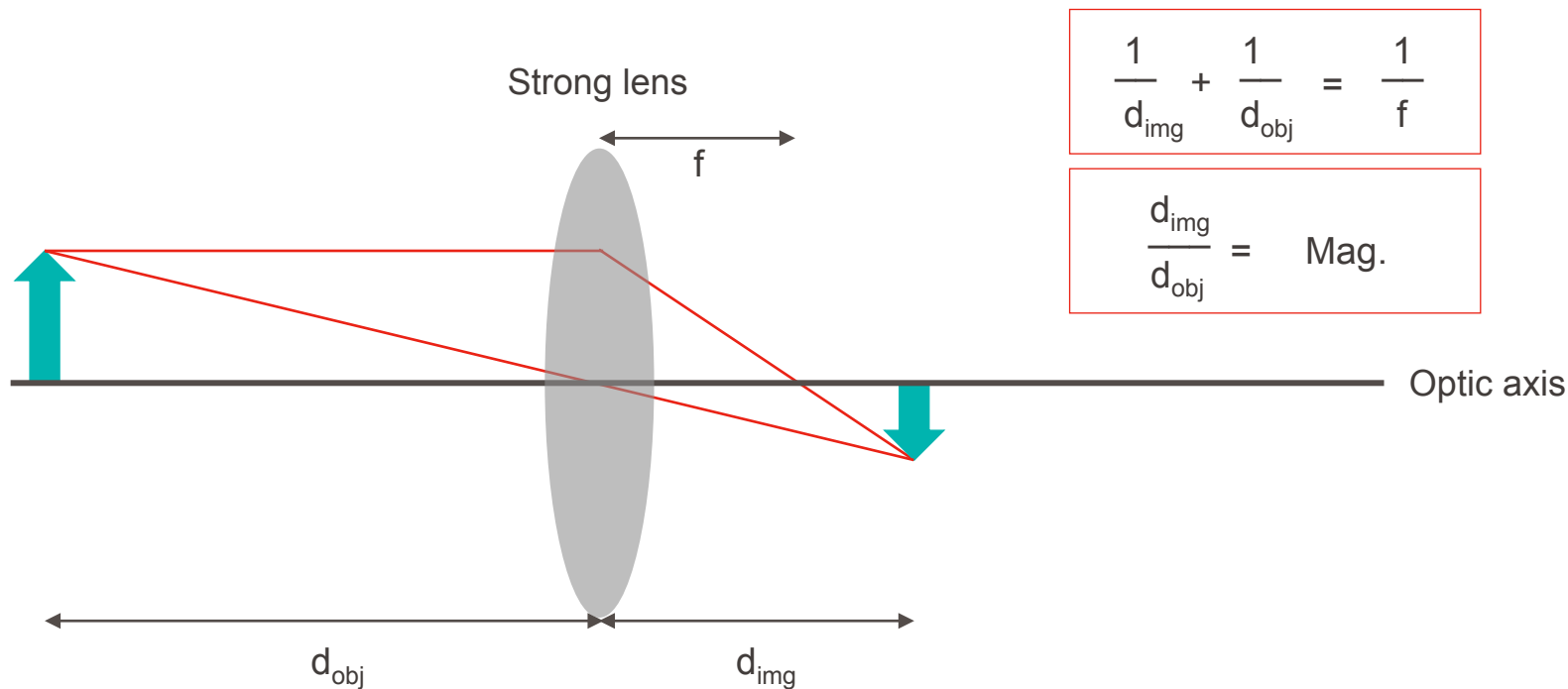
Lens produces a magnified (or de-magnified) image



Lens produces a de-magnified (or magnified) image

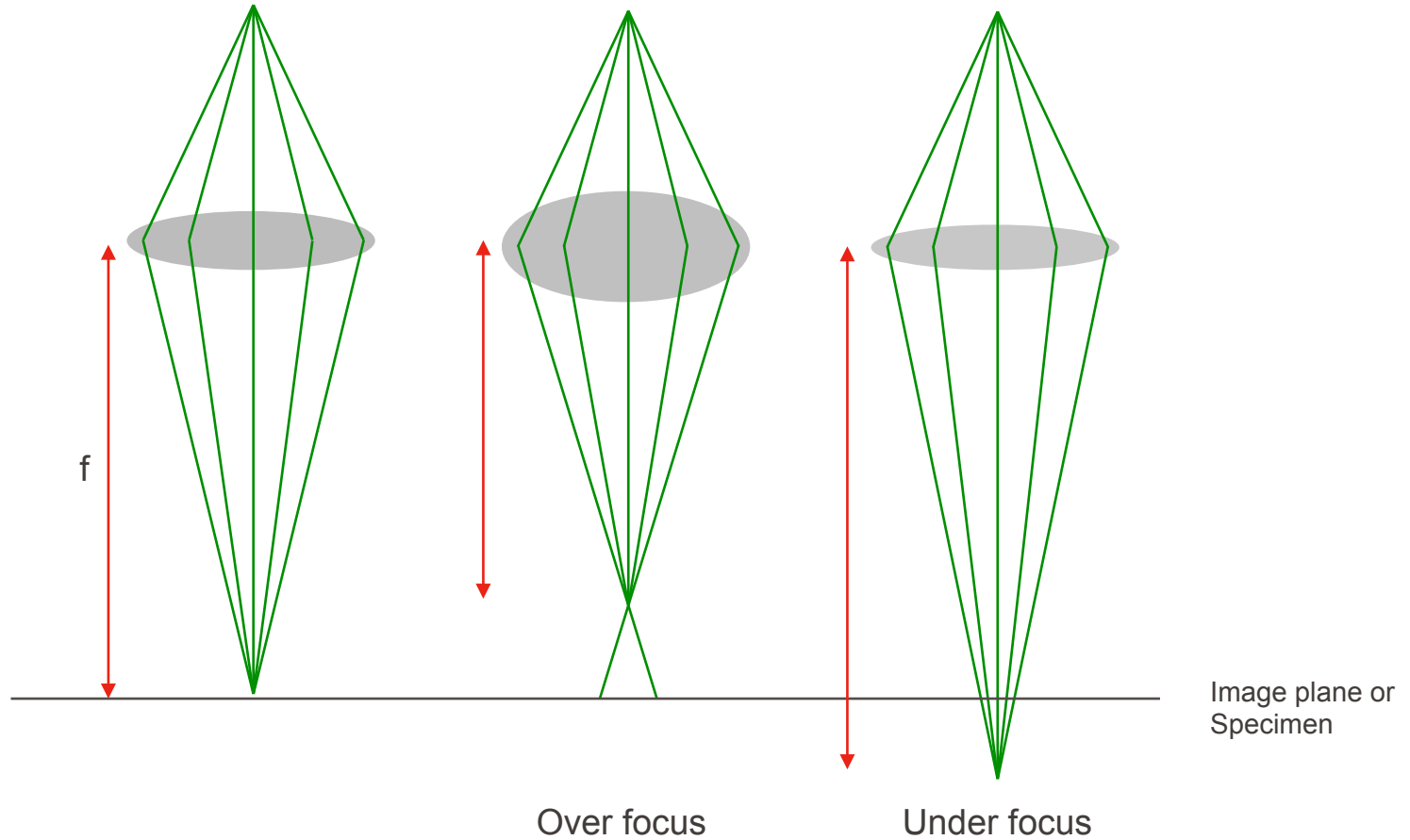


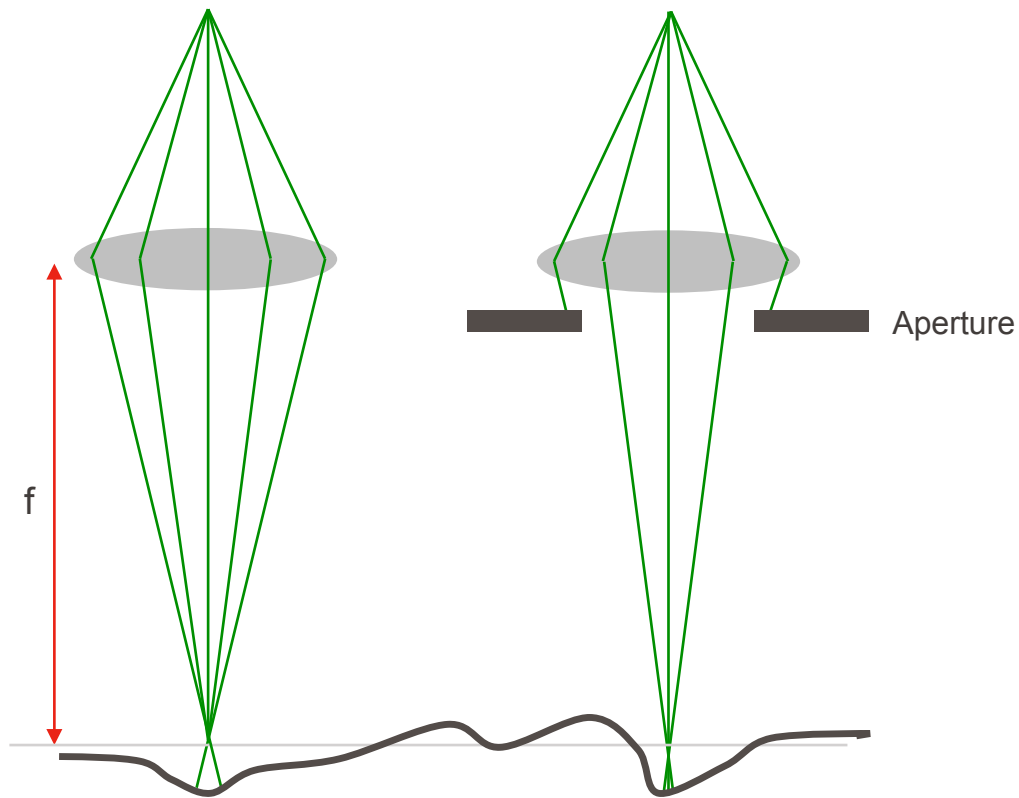
Lens produces a de-magnified (or magnified) image



**NOTE:**

Electron microscopes have more than one lens. Under this circumstance the image plane of the the  $n_{\text{th}}$  lens becomes the object plane of the  $(n+1)_{\text{th}}$  lens. The total magnification is the product of the magnification of all the lenses.





Smaller convergence angle  
Less probe current  
Larger depth of field?

# Lenses

- Lenses for light
  - Glass or polymer lenses
  - Deflection of light through changing refraction index

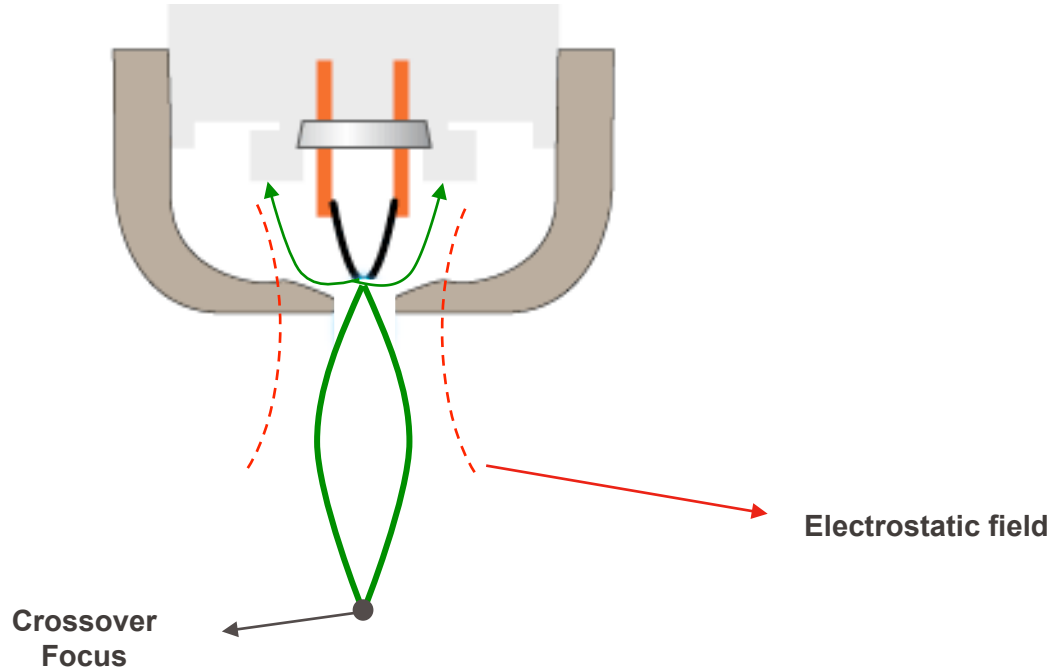


- Lenses for electrons
  - Variable focus
  - Electrostatic
  - Electromagnetic: Lorentz force

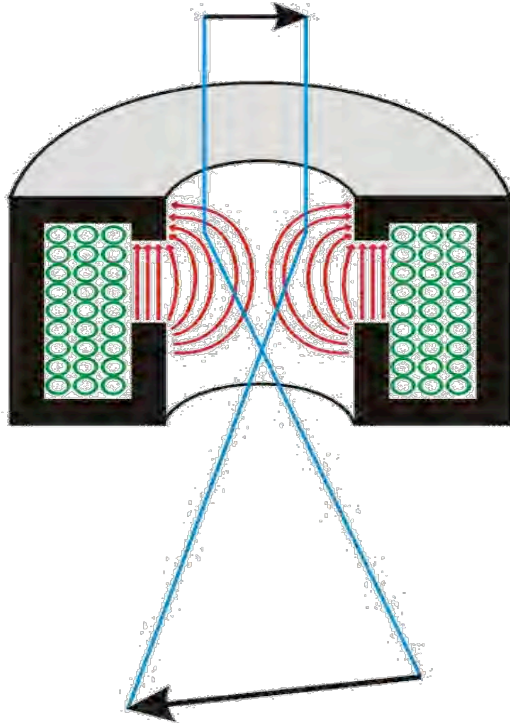




# Lenses - Electrostatic



# Lenses - Electromagnetic



An electromagnetic lens consists of a coil of copper wires inside an iron pole piece.

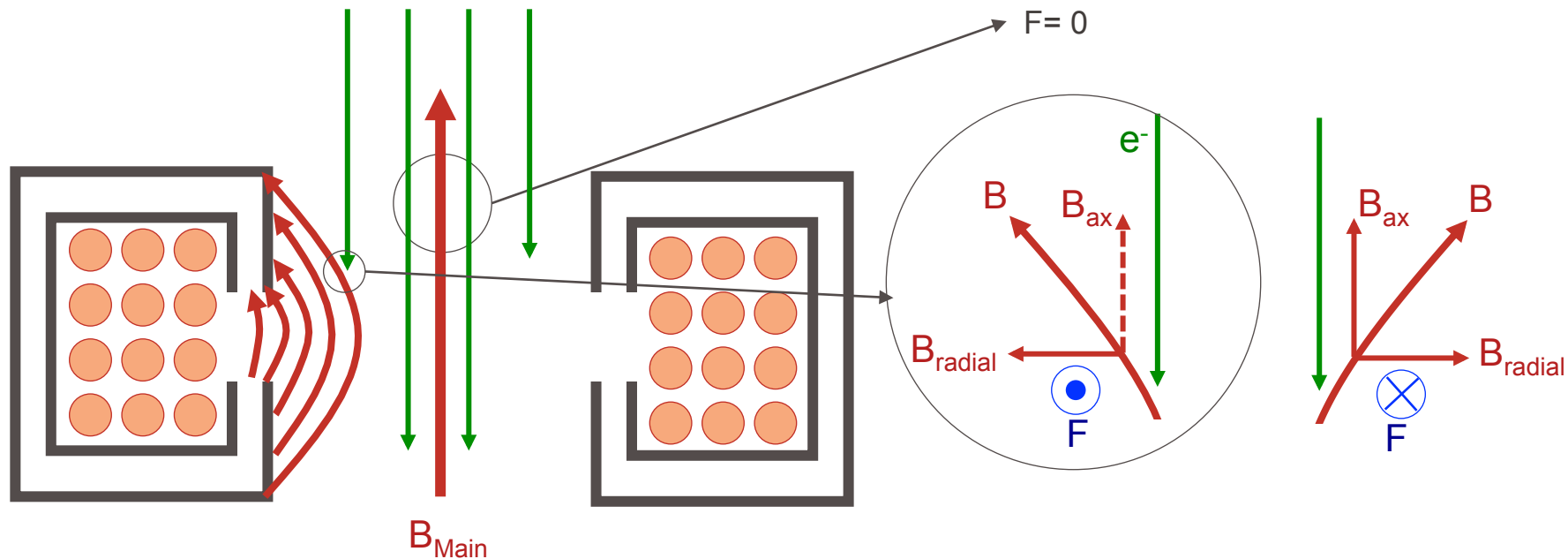
A current through the coils creates a magnetic field in the bore of the pole pieces which is used to converge the electron beam.

Lorentz force:  $\vec{F} = q \cdot (\vec{V} \times \vec{B})$

# Lenses - Electromagnetic

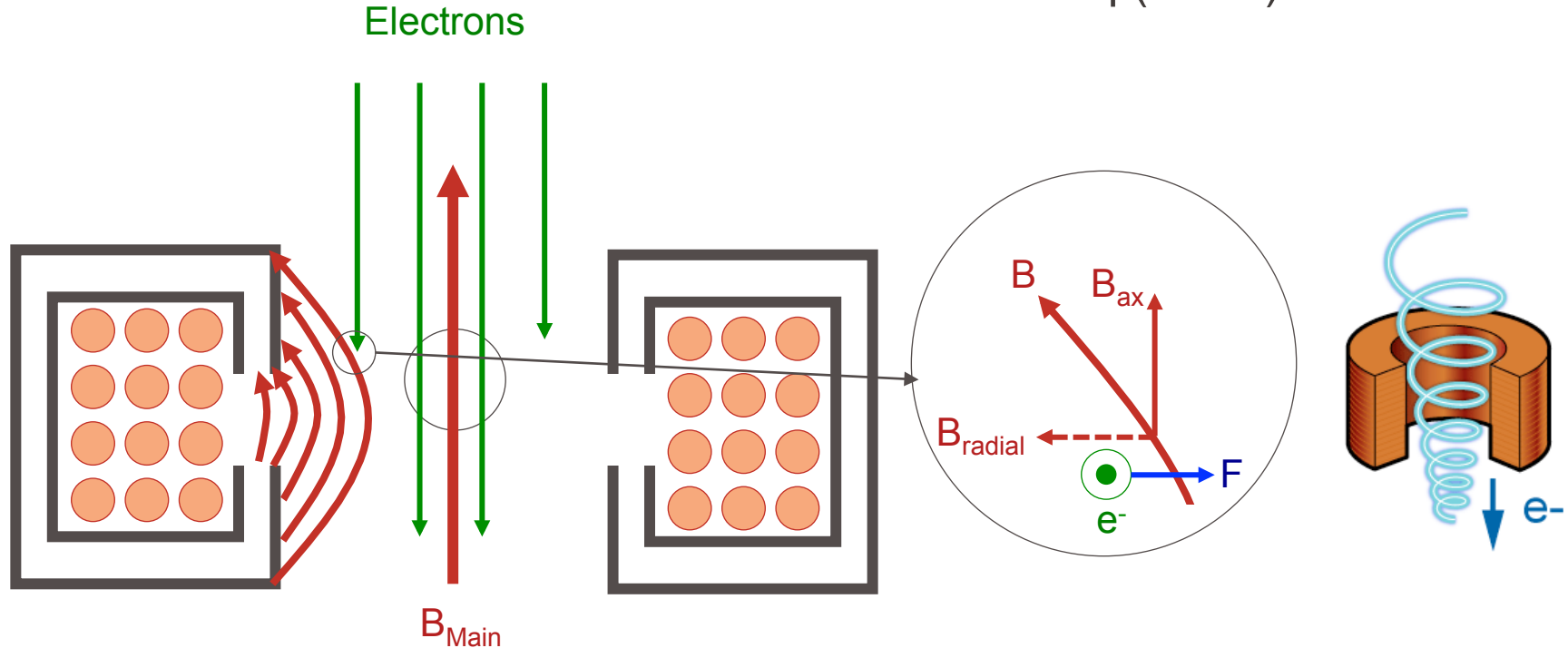
Lorentz force:  $\vec{F} = q \cdot (\vec{V} \times \vec{B})$

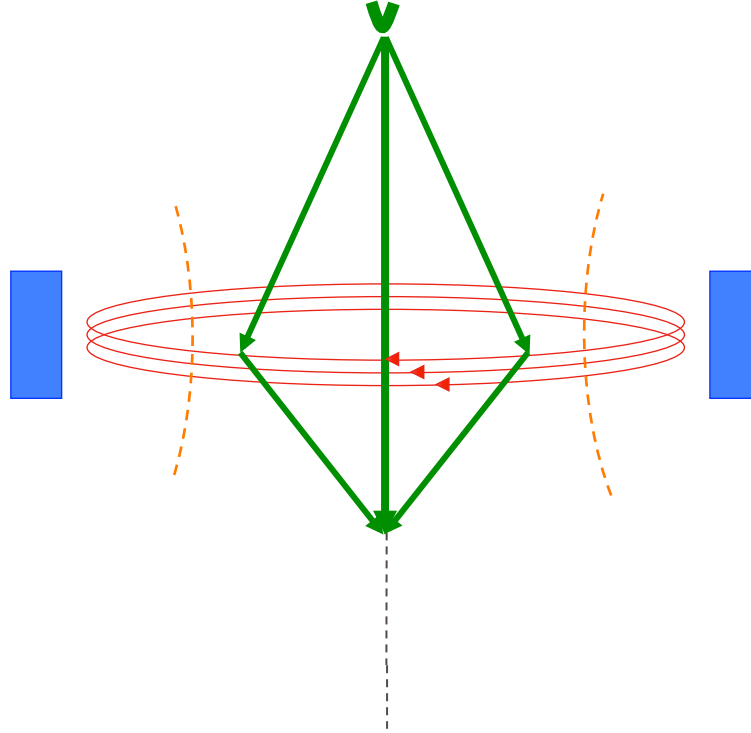
Electrons

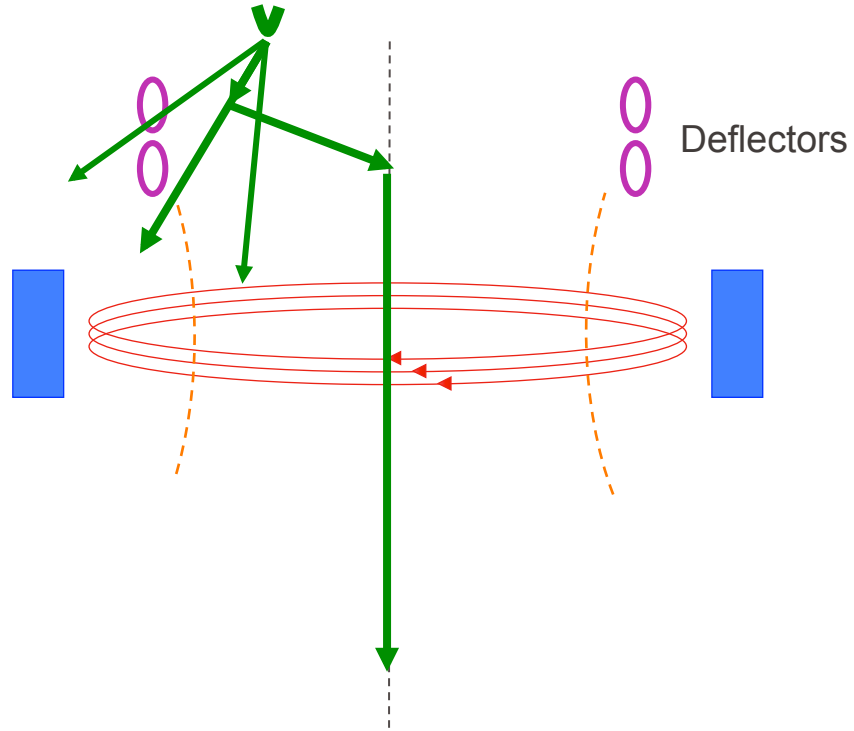


# Lenses - Electromagnetic

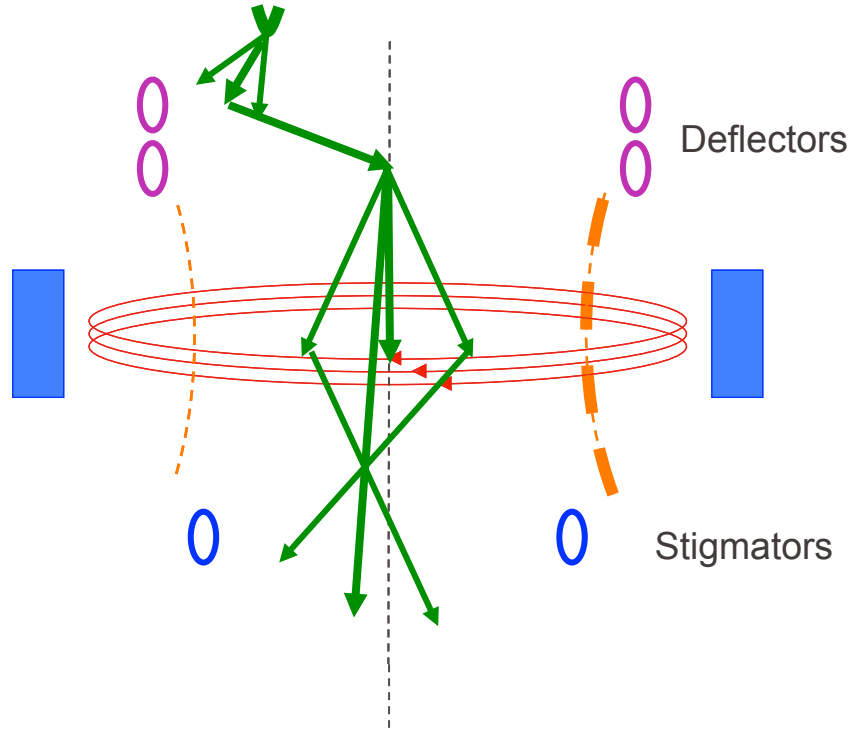
Lorenz force:  $\vec{F} = q \cdot (\vec{V} \times \vec{B})$

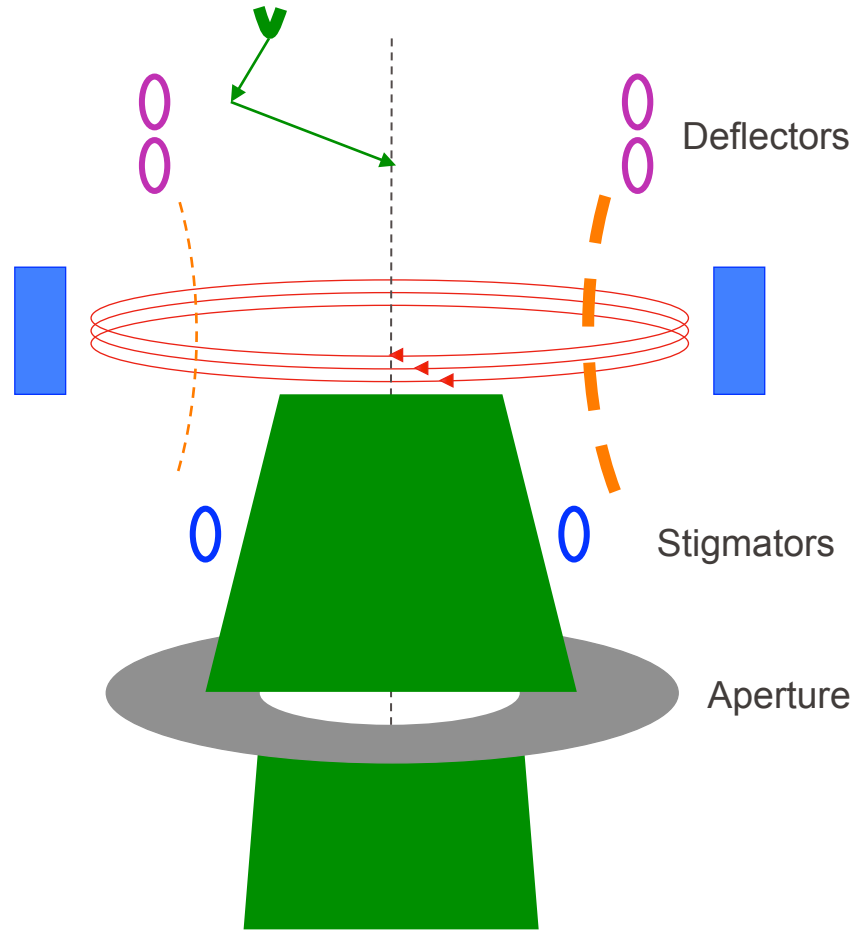




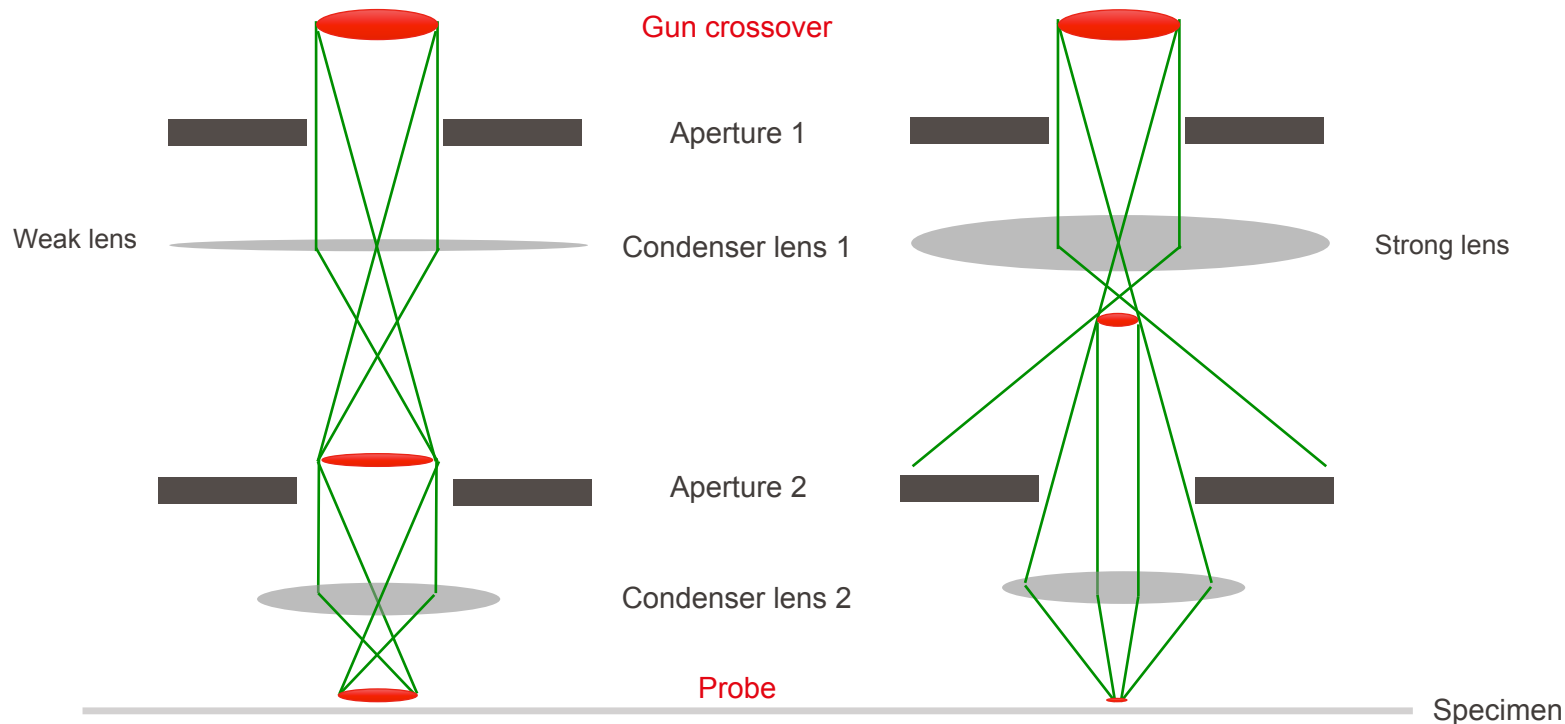


Local temperature changes  
Non uniform wiring  
**Non-uniform current/Magnetic field**



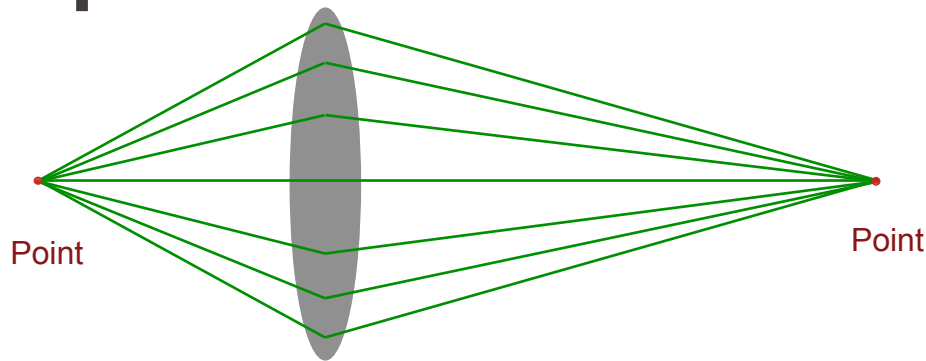






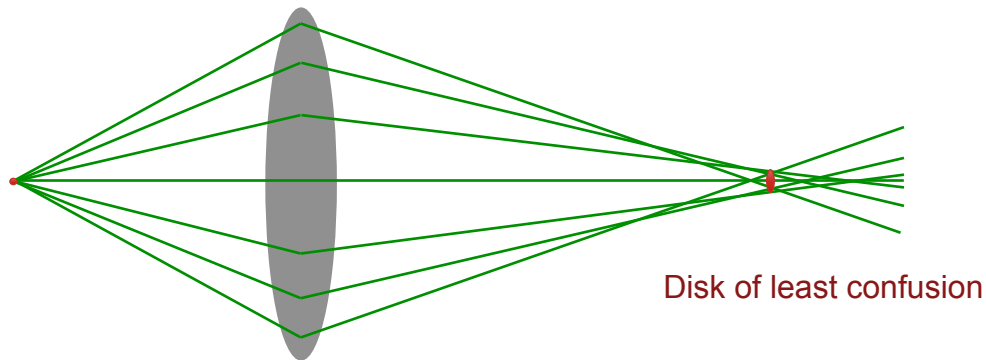
In scanning mode we need a narrow and convergent illumination.  
In fact, we use the lens system to de-magnify the image of the gun.

Ideal lens



A point source is focused to a point

Real lens



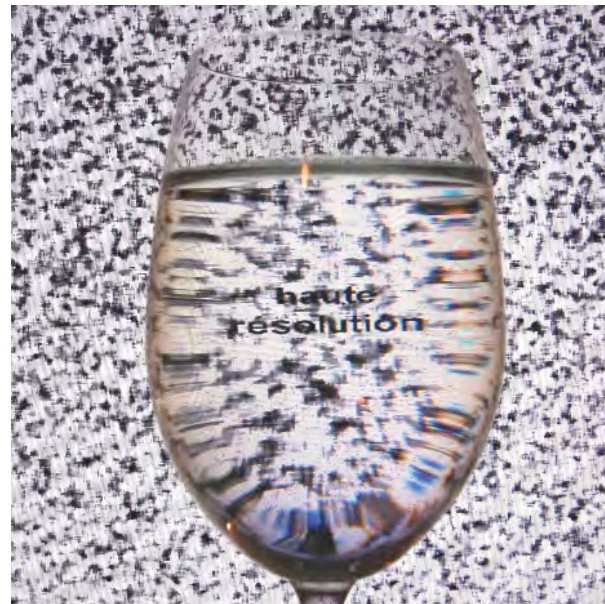
A point source is focused to a disk

**Lens aberrations reduce resolution!**

## ■ Lens aberrations

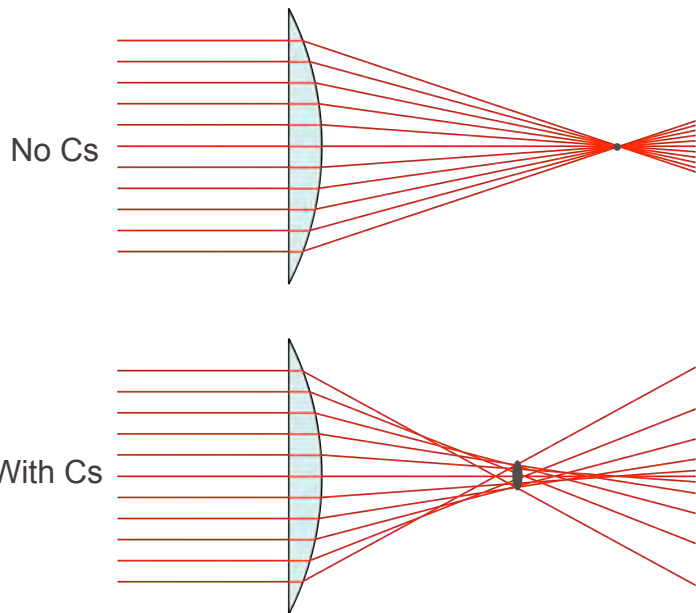
- Spherical aberration
- Chromatic aberration
- Astigmatism
- Diffraction effect

Lens aberrations are one of the main limitations to obtaining high spatial resolution.

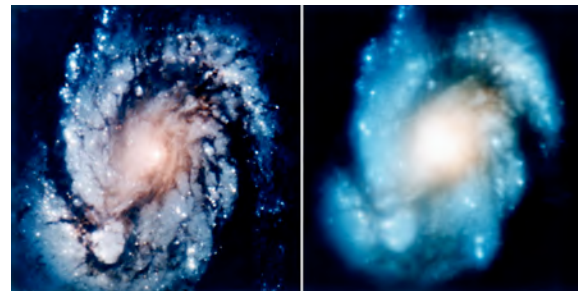


# Electron optics – Aberrations

- Spherical aberration (Cs)



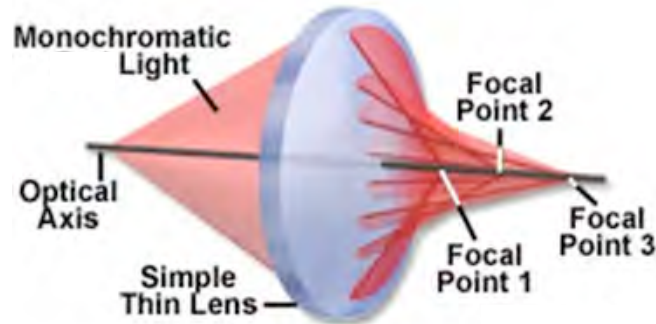
- Parallel rays that pass through the central region of the lens focus farther away than the rays that pass through the edges of the lens.
- Results in multiple focal points and thus a blurred image.
- Larger probe and lower resolution.



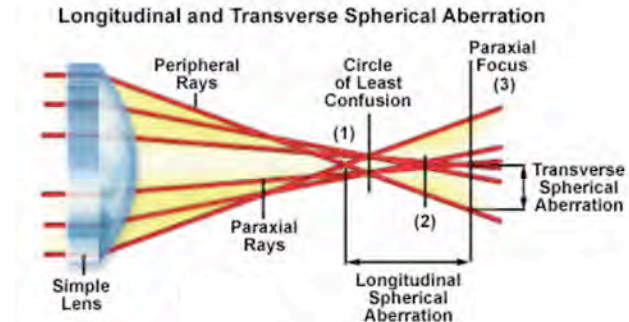
Core of the galaxy M100 ©NASA

# Electron optics – Aberrations

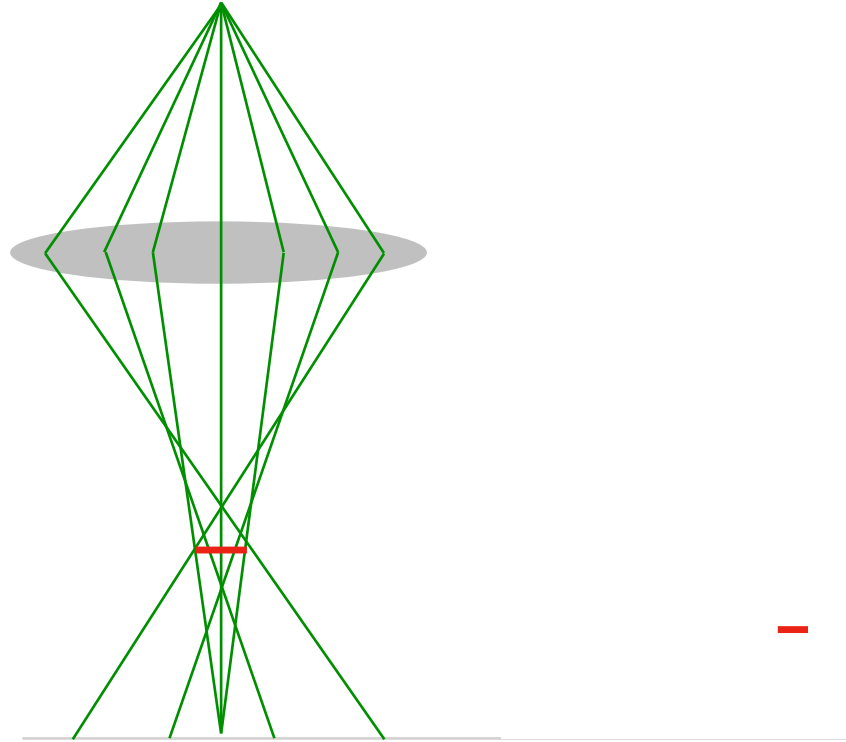
- Spherical aberration ( $C_s$ )



- Focal length depends on the distance from optical axis
- Image of the object is dispersed along the optical axis
- Circle of least confusion  
 $d_s = \frac{1}{2} C_s \lambda^3$



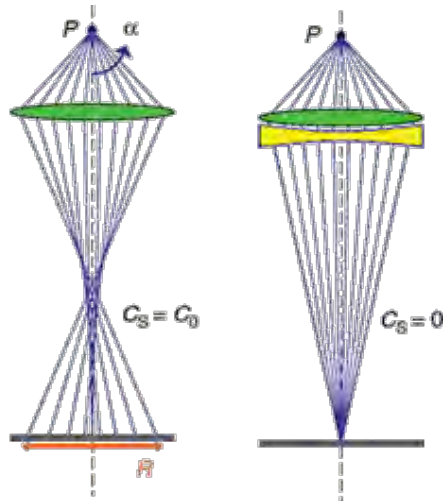
# Electron optics – Aberrations



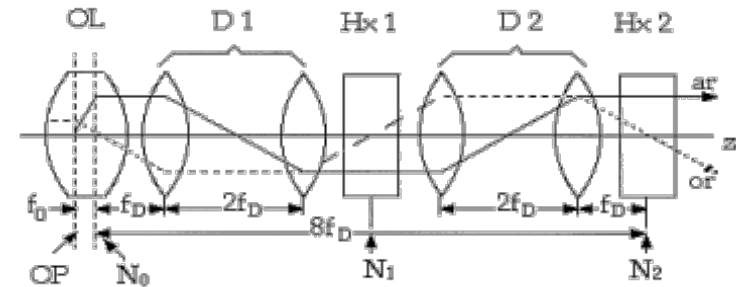
How to lower the effect of spherical aberration?

# Electron optics – Aberrations

- Cs correction in light optics
  - Correction with combination of convex and concave lenses

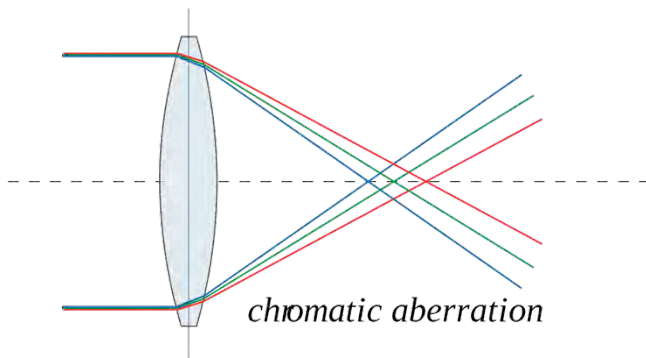


- Cs correction in electron optics
  - Correction with hexapole or quadrupole and octopole lenses



# Electron optics – Aberrations

- Chromatic aberration ( $C_c$ )

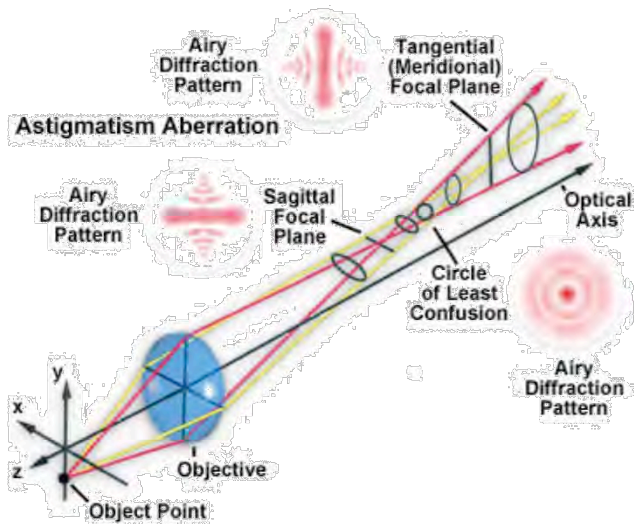


- Lens cannot focus all energies (wavelengths) to the same convergence point.
- Electrons of lower energy will be bent more strongly.
- Correcting the aberration is necessary, otherwise the resulting image would be blurry and delocalized, a form of aberration where periodic structures appear to extend beyond their physical boundaries.
- $C_c$  increases with source energy spread.



# Electron optics – Aberrations

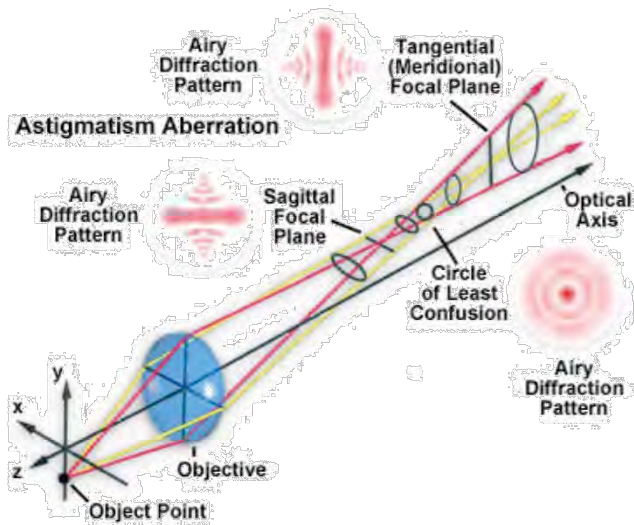
- Astigmatism



- Focal length varies for different axes of the lens.
- Image will appear “stretched” with changing the focus
- Caused by:
  - imperfections in the manufacturing of the pole-piece and the copper windings
  - Stray magnetic field

# Electron optics – Aberrations

- Astigmatism



Under focus image

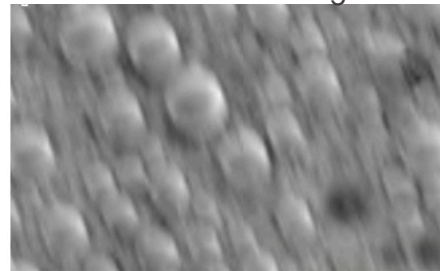
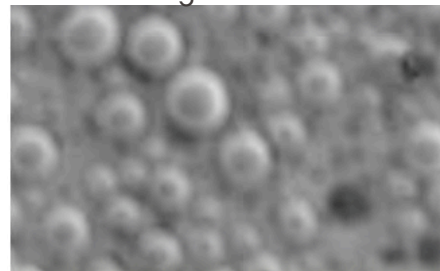
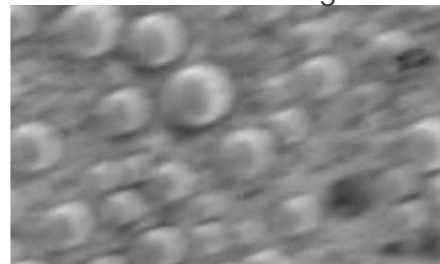


Image in focus

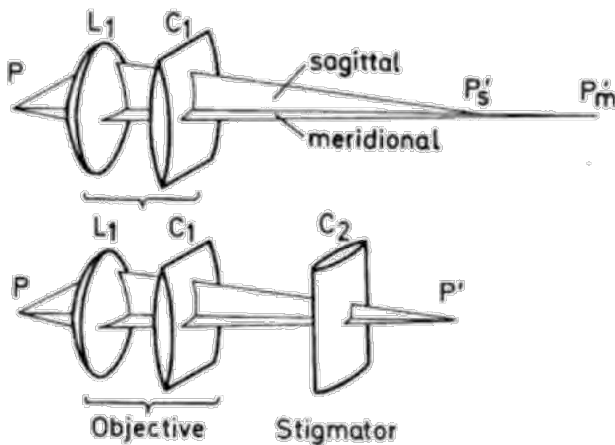


Over focus image



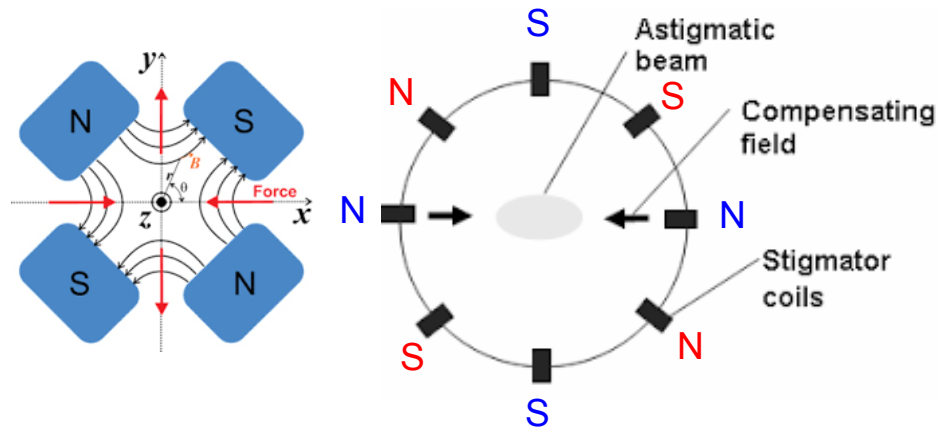
# Electron optics – Aberrations

- Astigmatism in light optics
  - Correction with cylindrical lenses



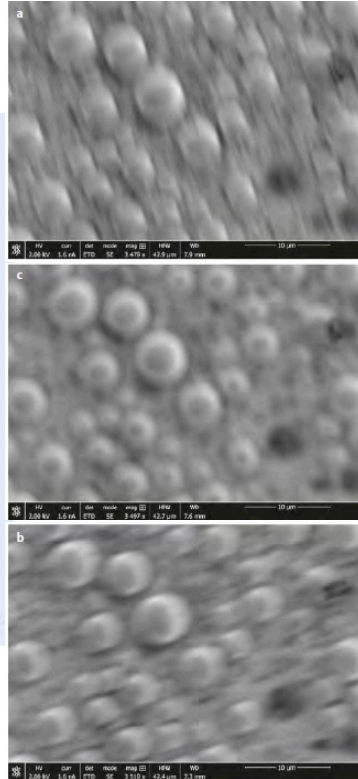
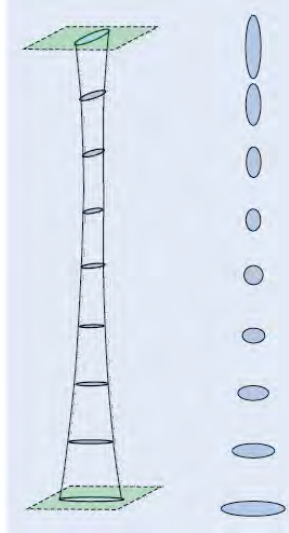
- Astigmatism correction in electron optics

- Correction with quadrupole lenses
- 2 quadrupole lenses under 45 degree allow to control strength and direction of correction

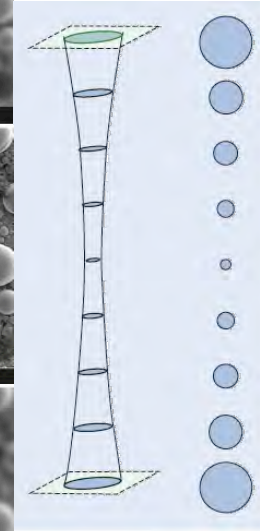
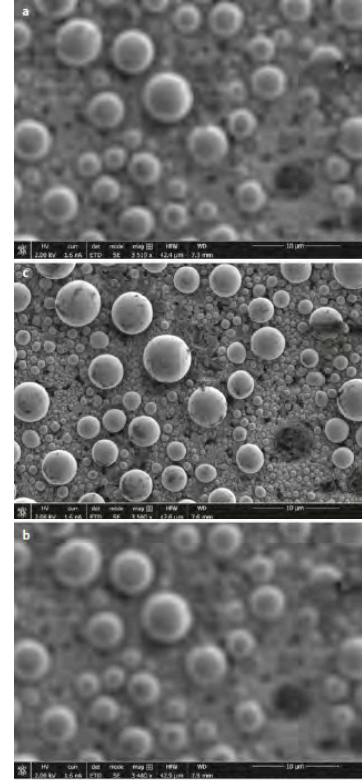


# Electron optics – Aberrations

With astigmatism



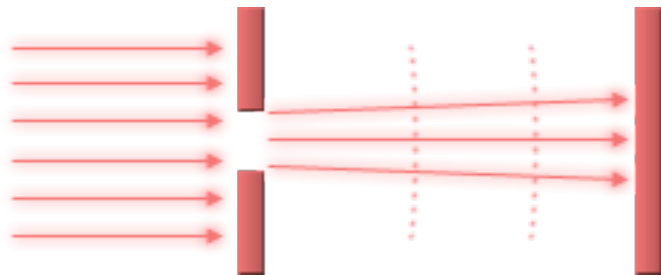
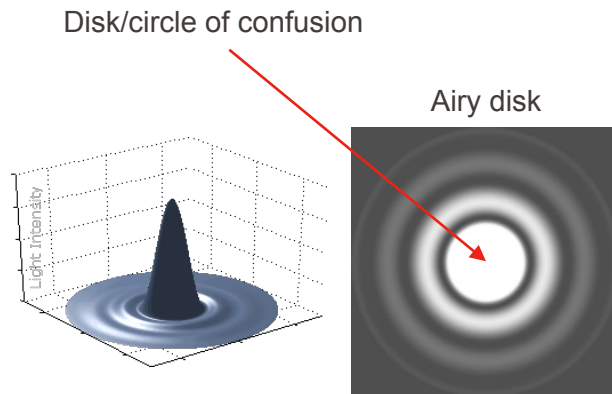
Astigmatism corrected



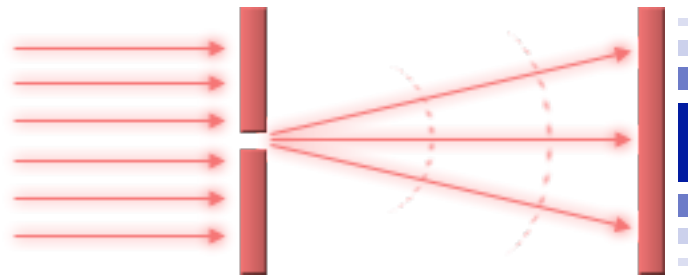
# Electron optics – Aberrations

## ■ Diffraction effect

- Light/electron rays passing through a small aperture will begin to diverge and interfere with one another
- → Diffraction | Airy disks



Large aperture



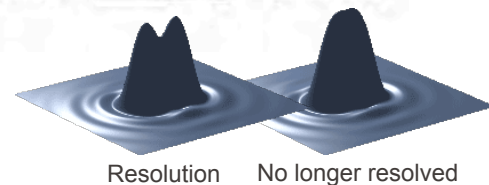
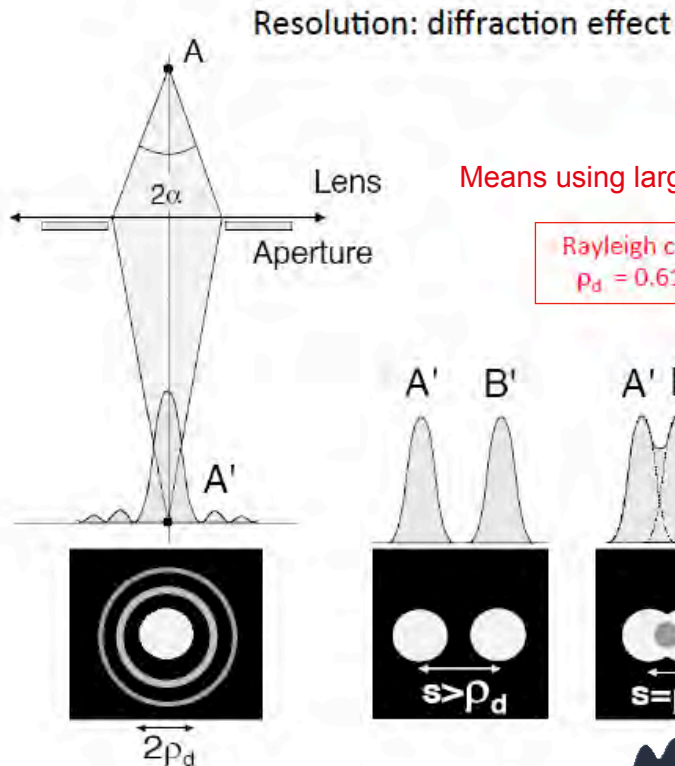
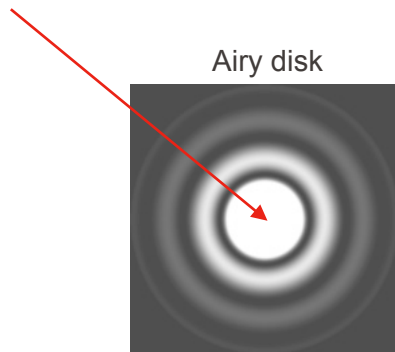
Small aperture

# Electron optics – Aberrations

## ■ Diffraction effect

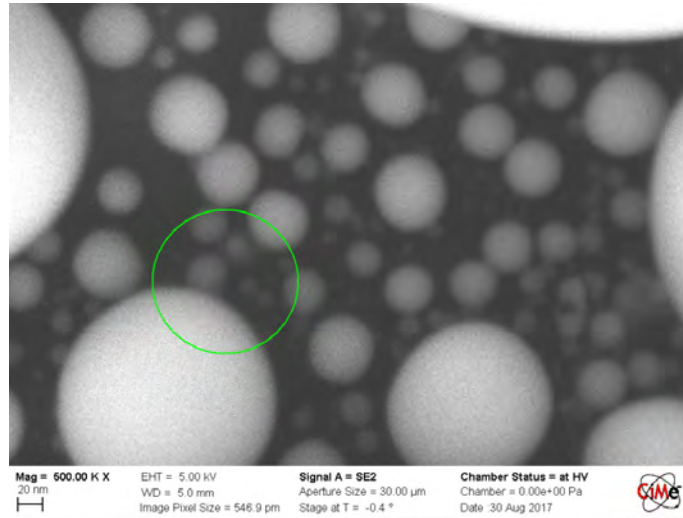
- Airy disks when light/electrons passing through a small opening (such as your camera's aperture)

Disk/circle of confusion

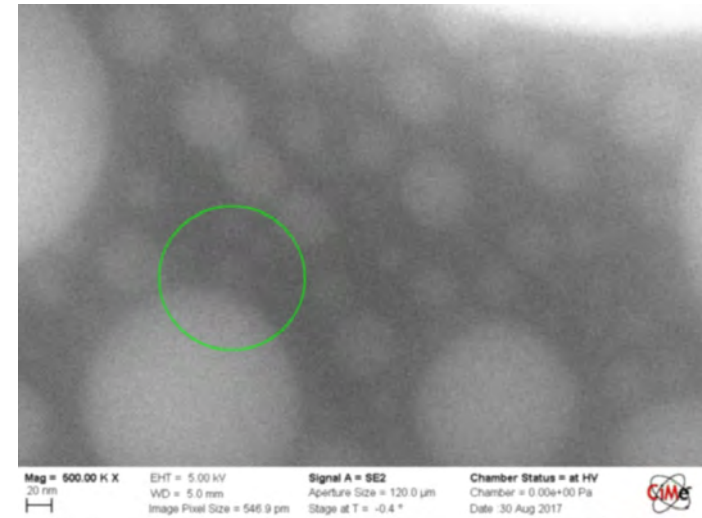


# Electron optics – Aberrations

Optimal Aperture size (30 $\mu$ m)



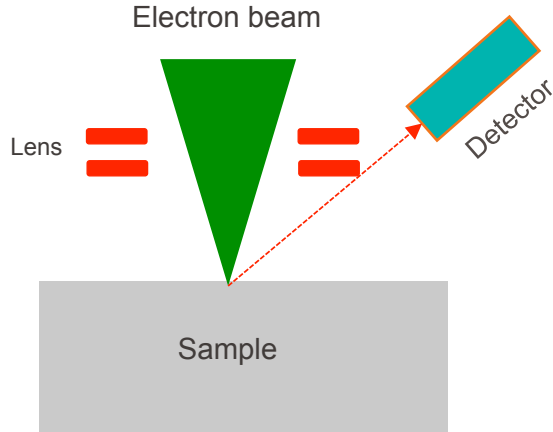
Large Aperture size (120 $\mu$ m)



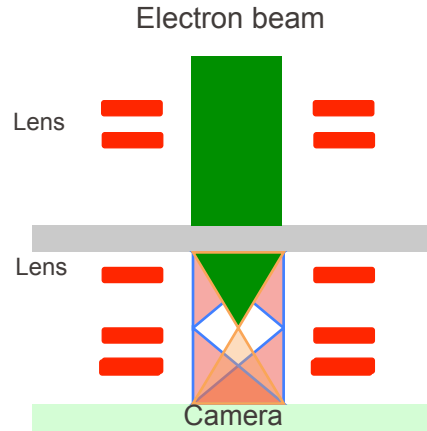
Though large apertures produce larger convergence angles (less diffraction effect), spherical aberration increases probe size and reduces resolution.

# Components of an EM

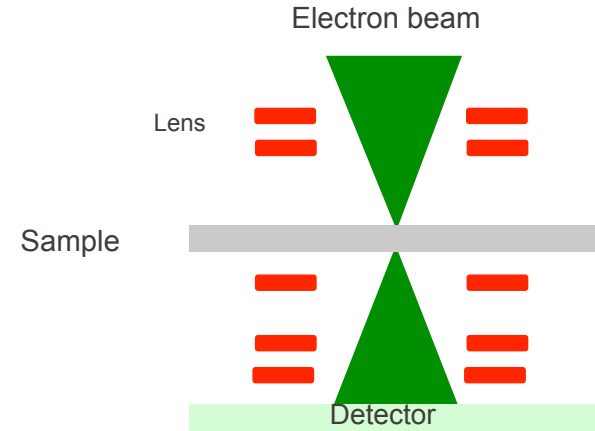
## SEM



## TEM



## STEM

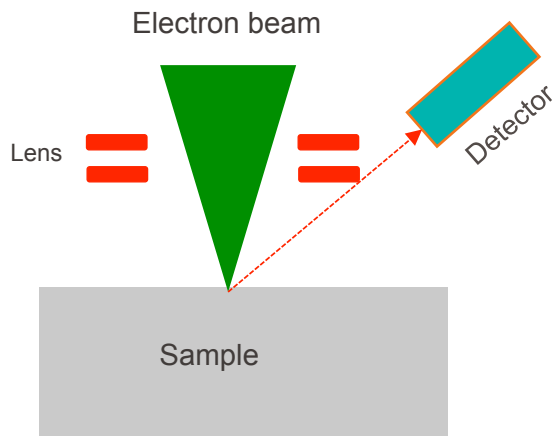


Vacuum system  
Electron gun  
Lenses  
**Detectors**



# Components of an EM

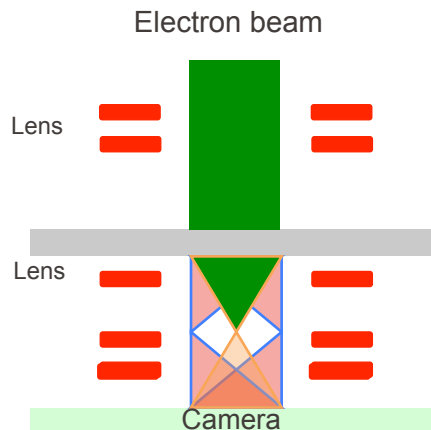
## SEM



Scintillator/Photomultiplier  
- Everhart-Thornley detector

Semiconductor BSE detector  
- Silicon diode with a p-n junction

## TEM



Phosphor screen

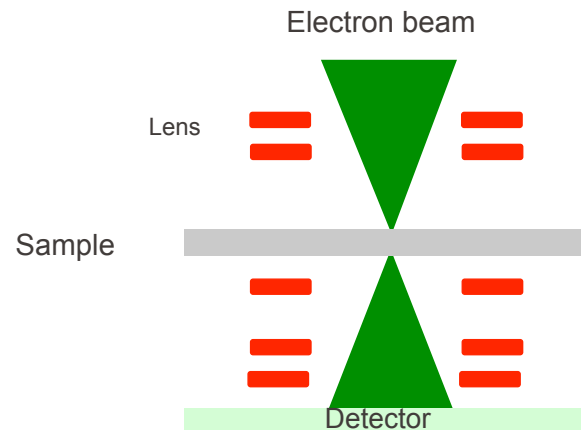
Negatives and image plates

Semiconductor charge-coupled devices (CCD)

Complementary metal-oxide-semiconductor (CMOS)

Direct electron detectors

## STEM



Disk/ring shape semiconductor detectors

Pixelated detectors

# Detectors

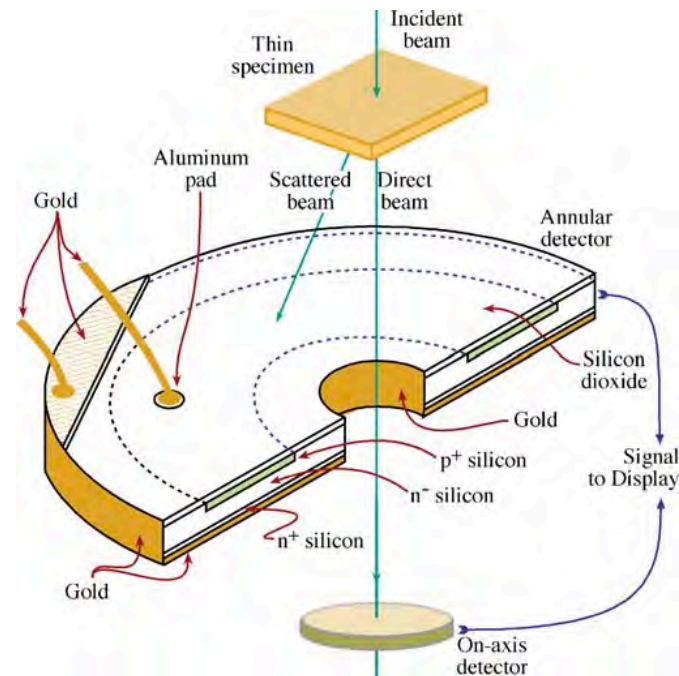
## How to “See” electrons

- **Semiconductor detectors**
- **Scintillator-Photomultiplier detectors**
- Charge-Coupled Device (CCD) Detectors
- Complementary metal-oxide semiconductors (CMOS)
- Direct electron cameras

# Electron detectors

## Semiconductor detectors

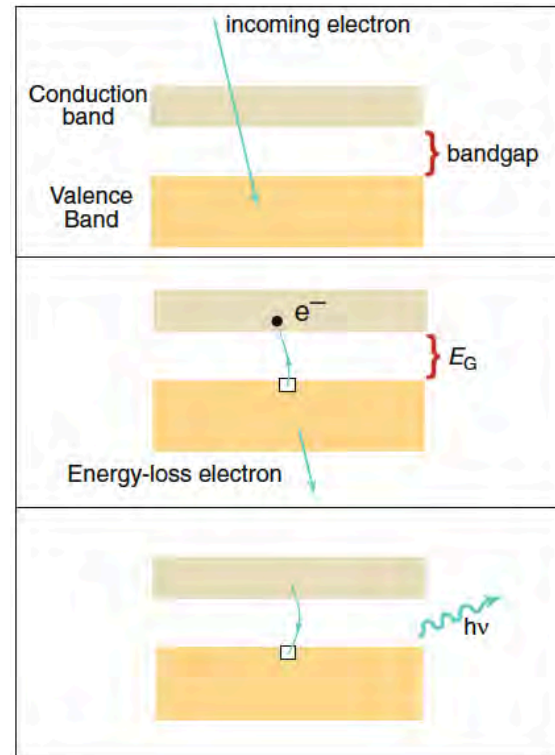
- Si diode with a p-n junction close to its surface collects
  - By doping the Si (e.g., by ion implantation of n-type impurity atoms into p-type Si or vice versa).
  - n-type | Gives free electrons to semiconductor
  - By evaporating a thin layer of Au on the surface of high-resistivity n-type Si, or evaporating Al onto p-type Si (i.e. surface-barrier detector or a Schottky diode).



# Electron detectors

## Semiconductor detectors

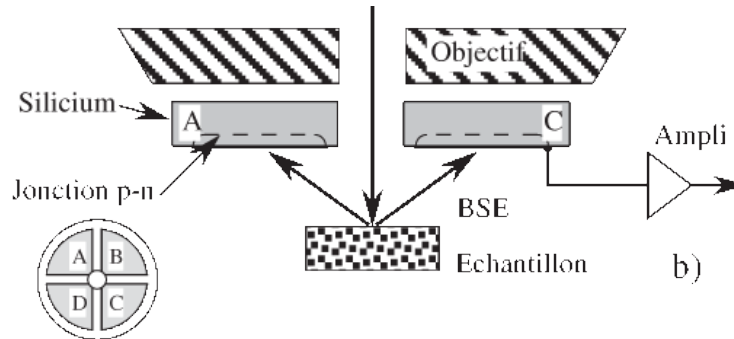
- When struck by the high-energy electrons, most of the beam energy is transferred to valence-band electrons in the Si which are excited across the band gap into the conduction band thus creating electron-hole pairs (3.6 eV / electron-hole pair).
- 10 keV  $\rightarrow$  ~2800 electrons
- Thus, the incoming electron signal is converted to a current in the external circuit between the surface contacts.



# Electron detectors

## Semiconductor detectors

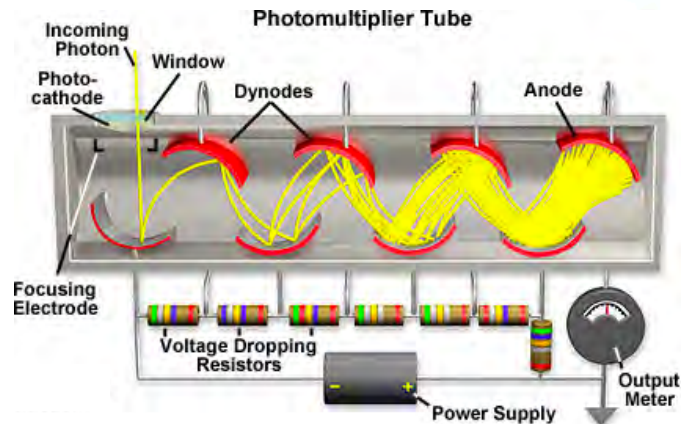
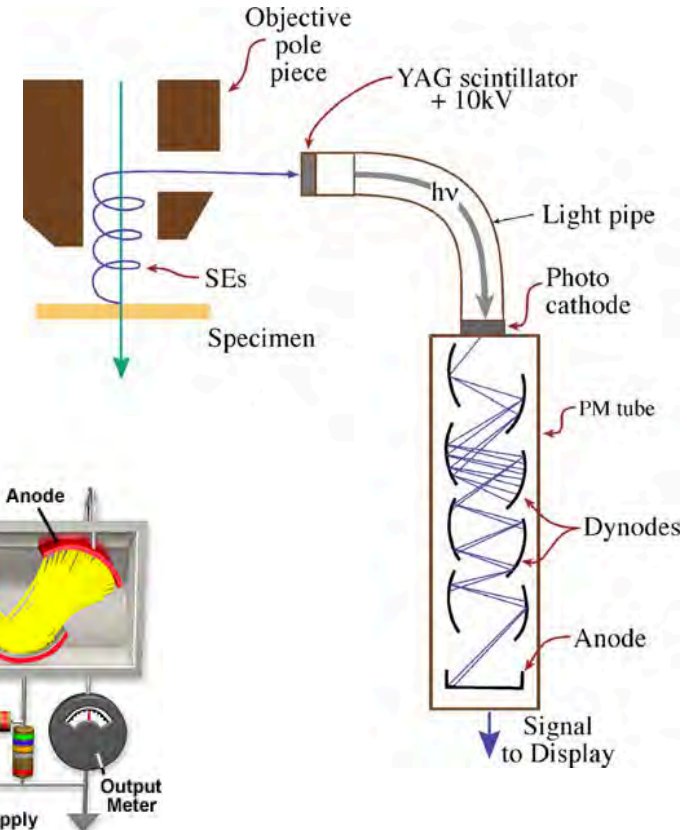
- Very efficient at picking up and amplifying electron signals
- Large collection angle
- Cheap and easily fabricate
- Slow | Not responsive to rapid changes in signal intensity (poor at TV frequency)
- Some diodes are split in 2 or 4 quadrants to bring spatial electron distribution information



# Electron detectors

## Scintillator-Photomultiplier

- A scintillator emits visible light when struck by electrons
- the light from the scintillator is amplified by a photomultiplier (PM) system, attached to the scintillator via a light pipe
- A collector (Faraday) cage with positive potential can be used to attract low-energy  $e^-$



# Electron detectors

## Scintillator-Photomultiplier

- Faster and with lower noise level compared with the semiconductor detectors
- → low-intensity images and TV-rate images are easily displayed
- Not as robust as the semiconductor detector, being even more susceptible to radiation damage, particularly after long-time exposure to the beam.
- Scintillator-PM combination is substantially more expensive and bulky compared to semiconductor